- **Direct Upgrades to TL05x, TL07x, and TL08x BiFET Operational Amplifiers**
- **Greater Than 2× Bandwidth (10 MHz) and 3× Slew Rate (45 V/μs) Than TL07x**
- **Ensured Maximum Noise Floor 17 nV/√Hz**
- **On-Chip Offset Voltage Trimming for Improved DC Performance**
- **Wider Supply Rails Increase Dynamic Signal Range to ±19 V**

description

The TLE207x series of JFET-input operational amplifiers more than double the bandwidth and triple the slew rate of the TL07x and TL08x families of BiFET operational amplifiers. Texas Instruments Excalibur process yields a typical noise floor of 11.6 nV/√Hz, 17-nV/√Hz ensured maximum, offering immediate improvement in noise-sensitive circuits designed using the TL07x. The TLE207x also has wider supply voltage rails, increasing the dynamic signal range for BiFET circuits to ±19 V. On-chip zener trimming of offset voltage yields precision grades for greater accuracy in dc-coupled applications. The TLE207x are pin-compatible with lower performance BiFET operational amplifiers for ease in improving performance in existing designs.

BiFET operational amplifiers offer the inherently higher input impedance of the JFET-input transistors, without sacrificing the output drive associated with bipolar amplifiers. This makes them better suited for interfacing with high-impedance sensors or very low-level ac signals. They also feature inherently better ac response than bipolar or CMOS devices having comparable power consumption.

The TLE207x family of BiFET amplifiers are Texas Instruments highest performance BiFETs, with tighter input offset voltage and ensured maximum noise specifications. Designers requiring less stringent specifications but seeking the improved ac characteristics of the TLE207x should consider the TLE208x operational amplifier family.

Because BiFET operational amplifiers are designed for use with dual power supplies, care must be taken to observe common-mode input voltage limits and output swing when operating from a single supply. DC biasing of the input signal is required and loads should be terminated to a virtual ground node at mid-supply. Texas Instruments TLE2426 integrated virtual ground generator is useful when operating BiFET amplifiers from single supplies.

The TLE207x are fully specified at ±15 V and ±5 V. For operation in low-voltage and/or single-supply systems, Texas Instruments LinCMOS families of operational amplifiers (TLC- and TLV-prefix) are recommended. When moving from BiFET to CMOS amplifiers, particular attention should be paid to slew rate and bandwidth requirements and output loading.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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TLE2071 AVAILABLE OPTIONS

T_A	V_{IO}max AT 25°C	PACKAGED DEVICES				
		SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	CERAMIC FLAT PACK (U)
0°C to 70°C	2 mV 4 mV	TLE2071ACD TLE2071CD	—	—	TLE2071ACP TLE2071CP	—
–40°C to 85°C	2 mV 4 mV	TLE2071AID TLE2071ID	—	—	TLE2071AIP TLE2071IP	—
–55°C to 125°C	2 mV 4 mV	— —	TLE2071AMFK TLE2071MFK	TLE2071AMJG TLE2071MJG	— —	TLE2071AMU TLE2071MU

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2071ACDR).

TLE2072 AVAILABLE OPTIONS

T_A	V_{IO}max AT 25°C	PACKAGED DEVICES				
		SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	CERAMIC FLAT PACK (U)
0°C to 70°C	3.5 mV 6 mV	TLE2072ACD TLE2072CD	—	—	TLE2072ACP TLE2072CP	—
–40°C to 85°C	3.5 mV 6 mV	TLE2072AID TLE2072ID	—	—	TLE2072AIP TLE2072IP	—
–55°C to 125°C	3.5 mV 6 mV	—	TLE2072AMFK TLE2072MFK	TLE2072AMJG TLE2072MJG	—	TLE2072AMU TLE2072MU

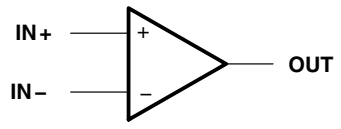
† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2072ACDR).

TLE2074 AVAILABLE OPTIONS

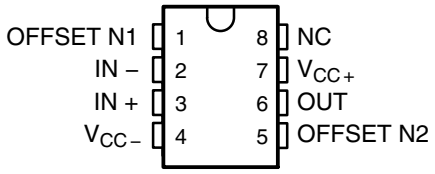
T_A	V_{IO}max AT 25°C	PACKAGED DEVICES				
		SMALL OUTLINE† (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	CERAMIC FLAT PACK (W)
0°C to 70°C	3 mV 5 mV	TLE2074ACDW TLE2074CDW	—	—	TLE2074ACN TLE2074CN	—
–40°C to 85°C	3 mV 5 mV	TLE2074AIDW TLE2074IDW	—	—	TLE2074AIN TLE2074IN	—
–55°C to 125°C	3 mV 5 mV	—	TLE2074AMFK TLE2074MFK	TLE2074AMJ TLE2074MJ	—	TLE2074AMW TLE2074MW

† The DW packages are available taped and reeled. Add R suffix to device type (e.g., TLE2074ACDWR).

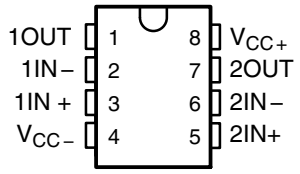
symbol



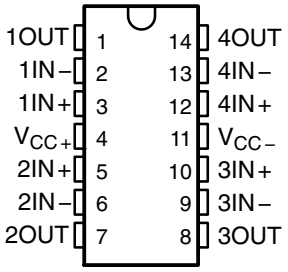
TLE2071 AND TLE2071A
D, JG, OR P PACKAGE
(TOP VIEW)



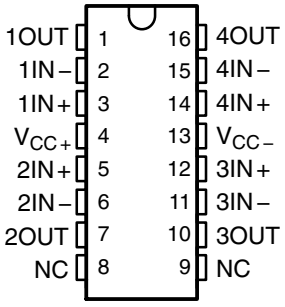
TLE2072 AND TLE2072A
D, JG, OR P PACKAGE
(TOP VIEW)



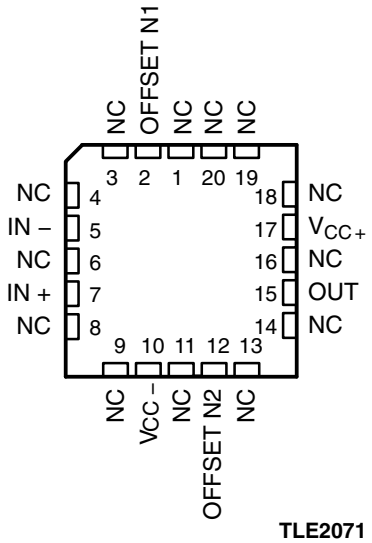
TLE2074 AND TLE2074A
J, N, OR W PACKAGE
(TOP VIEW)



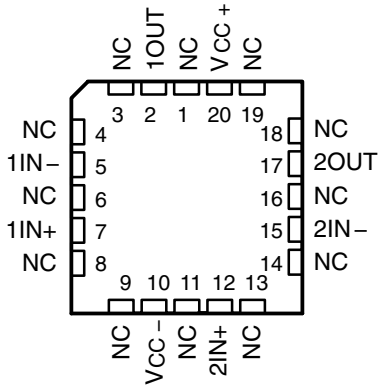
TLE2074 AND TLE2074A
DW PACKAGE
(TOP VIEW)



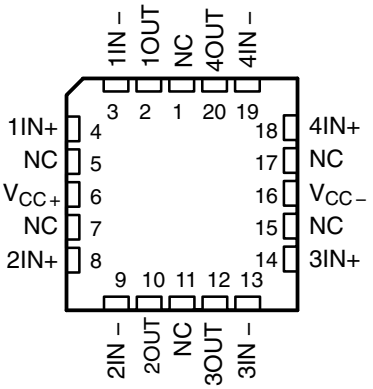
TLE2071M AND TLE2071AM
FK PACKAGE
(TOP VIEW)



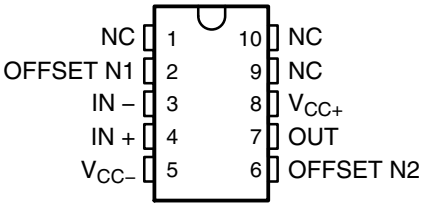
TLE2072M AND TLE2072AM
FK PACKAGE
(TOP VIEW)



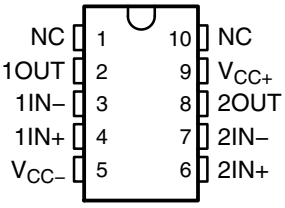
TLE2074M AND TLE2074AM
FK PACKAGE
(TOP VIEW)



TLE2071 AND TLE2071A
U PACKAGE
(TOP VIEW)

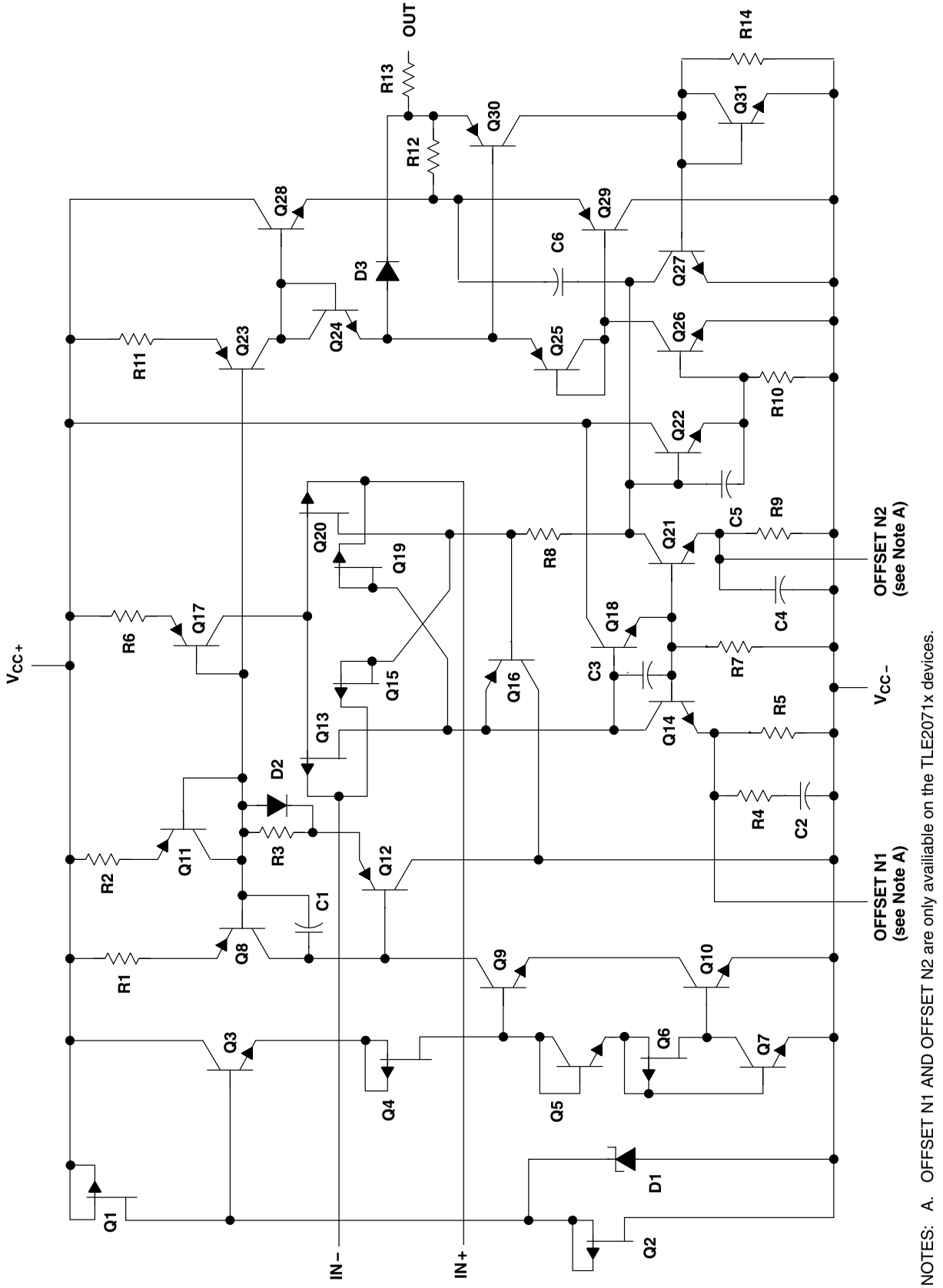


TLE2072 AND TLE2072A
U PACKAGE
(TOP VIEW)



NC – No internal connection

equivalent schematic



NOTES: A. OFFSET N1 AND OFFSET N2 are only availiable on the TLE2071x devices.

equivalent schematic (continued)

ACTUAL DEVICE COMPONENT COUNT			
COMPONENT	**TLE2071**	**TLE2072**	**TLE2074**
Transistors	33	57	114
Resistors	25	37	74
Diodes	8	5	10
Capacitors	6	11	22

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC+} (see Note 1) . . . . . 19 V
Supply voltage, V_{CC-} (see Note 1) . . . . . –19 V
Differential input voltage range, V_{ID} (see Note 2) . . . . . V_{CC+} to V_{CC-}
Input voltage range, V_I (any input) . . . . . V_{CC+} to V_{CC-}
Input current, I_I (each input) . . . . . ±1 mA
Output current, I_O (each output) . . . . . ±80 mA
Total current into V_{CC+} . . . . . 160 mA
Total current out of V_{CC-} . . . . . 160 mA
Duration of short-circuit current at (or below) 25°C (see Note 3) . . . . . unlimited
Package thermal impedance, θ_{JA} (see Notes 4 and 5): D package . . . . . 97.1°C/W
DW package . . . . . 57.3°C/W
N package . . . . . 79.7°C/W
P package . . . . . 84.6°C/W
Package thermal impedance, θ_{JC} (see Notes 4 and 5): FK package . . . . . 5.6°C/W
J package . . . . . 15.1°C/W
JG package . . . . . 14.5°C/W
U package . . . . . 14.7°C/W
W package . . . . . 10°C/W
Operating free-air temperature range, T_A: C suffix . . . . . 0°C to 70°C
I suffix . . . . . –40°C to 85°C
M suffix . . . . . –55°C to 125°C
Storage temperature range . . . . . –65°C to 150°C
Case temperature for 60 seconds: FK package . . . . . 260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW or N package . . . . . 260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J, JG, U, or W package . . . . . 300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
2. Differential voltages are at the noninverting input with respect to the inverting input.
3. The output may be shorted to either supply. Temperatures and/or supply voltages must be limited to ensure that the maximum dissipation rate is not exceeded.
4. Maximum power dissipation is a function of $T_J(max)$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) – T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
5. The package thermal impedance is calculated in accordance with JESD 51-7 (plastic) or MIL-STD-883 Method 1012 (ceramic).

recommended operating conditions

		C SUFFIX		I SUFFIX		M SUFFIX		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{CC±}$		±2.25	±19	±2.25	±19	±2.25	±19	V
Common-mode input voltage, V_{IC}	$V_{CC±}$ = ±5 V	–0.9	5	–0.8	5	–0.8	5	V
	$V_{CC±}$ = ±15 V	–10.9	15	–10.8	15	–10.8	15	
Operating free-air temperature, T_A		0	70	–40	85	–55	125	°C

TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071C			TLE2071AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		0.34	4		0.3	2	mV
				Full range			6			4	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		3.2	29		3.2	29	μV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		5	100		5	100	pA
				Full range			1.4			1.4	nA
I_{IB}	Input bias current			25°C		15	175		15	175	pA
				Full range			5			5	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
				Full range	5 to −0.9			5 to −0.9			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 μA		25°C	3.8	4.1		3.8	4.1		V
				Full range	3.7			3.7			
		I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
				Full range	3.4			3.4			
		I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
				Full range	1.5			1.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 μA		25°C	−3.5	−4.2		−3.5	−4.2		V
				Full range	−3.4			−3.4			
		I_O = 2 mA		25°C	−3.7	−4.1		−3.7	−4.1		
				Full range	−3.6			−3.6			
		I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
				Full range	−1.5			−1.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ± 2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	100		90	100		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	106		95	106		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		11			11		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
				Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

† Full range is 0°C to 70°C.

TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071C			TLE2071AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current	V_O = 0,	No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
				Full range			2.2			2.2	
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

† Full range is 0°C to 70°C.

TLE2071C operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2071C			TLE2071AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	23			23			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	23			23			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is 0°C to 70°C.

TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071C			TLE2071AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		0.49	4		0.47	2	mV
				Full range			6			4	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		3.2	29		3.2	29	μV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		6	100		6	100	pA
				Full range			1.4			1.4	nA
I_{IB}	Input bias current			25°C		20	175		20	175	pA
				Full range			5			5	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	15 to −11	15 to −11.9		15 to −11	15 to −11.9		V
				Full range	15 to −10.9			15 to −10.9			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 μA		25°C	13.8	14.1		13.8	14.1		V
				Full range	13.7			13.7			
		I_O = −2 mA		25°C	13.5	13.9		13.5	13.9		
				Full range	13.4			13.4			
		I_O = −20 mA		25°C	11.5	12.3		11.5	12.3		
				Full range	11.5			11.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 μA		25°C	−13.8	−14.2		−13.8	−14.2		V
				Full range	−13.7			−13.7			
		I_O = 2 mA		25°C	−13.5	−14		−13.5	−14		
				Full range	−13.4			−13.4			
		I_O = 20 mA		25°C	−11.5	−12.4		−11.5	−12.4		
				Full range	−11.5			−11.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	109		90	109		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	118		95	118		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		7.5			7.5		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
				Full range	79			79			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			81			

† Full range is 0°C to 70°C.

TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071C			TLE2071AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current	V_O = 0,	No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
				Full range			2.2			2.2	
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	−30	−45		−30	−45		mA
			V_{ID} = −1 V		30	48		30	48		

† Full range is 0°C to 70°C.

TLE2071C operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2071C			TLE2071AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = 10 V, R_L = 2 kΩ, See Figure 1	A_{VD} = −1, C_L = 100 pF,	25°C	30	40		30	40		V/μs
				Full range	27			27			
SR−	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	27			27			
t_s	Settling time	A_{VD} = −1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = −1, C_L = 25 pF	25°C	478	637		478	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

† Full range is 0°C to 70°C.

TLE2071I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071I			TLE2071AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω,		25°C		0.34	4		0.3	2	mV
				Full range			7.6			5.6	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		3.2	29		3.2	29	µV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		5	100		5	100	pA
				Full range			5			5	nA
I_{IB}	Input bias current			25°C		15	175		15	175	pA
				Full range			10			10	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
				Full range	5 to −0.8			5 to −0.8			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA		25°C	3.8	4.1		3.8	4.1		V
				Full range	3.7			3.7			
		I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
				Full range	3.4			3.4			
		I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
				Full range	1.5			1.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA		25°C	−3.8	−4.2		−3.8	−4.2		V
				Full range	−3.7			−3.7			
		I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.4			−3.4			
		I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
				Full range	−1.5			−1.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	100		90	100		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	106		95	106		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		11			11		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
				Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

† Full range is −40°C to 85°C.

TLE2071I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071I			TLE2071AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current	V_O = 0, No load		25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
				Full range			2.2			2.2	
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

† Full range is −40°C to 85°C.

TLE2071I operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2071I			TLE2071AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF, R_L = 2 kΩ, See Figure 1		25°C		35			35		V/μs
				Full range	22			22			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	22			22			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is −40°C to 85°C.

TLE2071I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071I			TLE2071AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω,		25°C		0.49	4		0.47	2	mV
				Full range			7.6			5.6	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		3.2	29		3.2	29	µV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		6	100		6	100	pA
				Full range			5			5	nA
I_{IB}	Input bias current			25°C		20	175		20	175	pA
				Full range			10			10	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	15 to −11	15 to −11.9		15 to −11	15 to −11.9		V
				Full range	15 to −10.8			15 to −10.8			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA		25°C	13.8	14.1		13.8	14.1		V
				Full range	13.7			13.7			
		I_O = −2 mA		25°C	13.5	13.9		13.5	13.9		
				Full range	13.4			13.4			
		I_O = −20 mA		25°C	11.5	12.3		11.5	12.3		
				Full range	11.5			11.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA		25°C	−13.8	−14.2		−13.8	−14.2		V
				Full range	−13.7			−13.7			
		I_O = 2 mA		25°C	−13.5	−14		−13.5	−14		
				Full range	−13.4			−13.4			
		I_O = 20 mA		25°C	−11.5	−12.4		−11.5	−12.4		
				Full range	−11.5			−11.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ± 10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	109		90	109		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	118		95	118		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		7.5			7.5		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
				Full range	79			79			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

† Full range is −40°C to 85°C.

TLE2071I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071I			TLE2071AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current	V_O = 0,	No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
				Full range			2.2			2.2	
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	−30	−45		−30	−45		mA
			V_{ID} = −1 V		30	48		30	48		

† Full range is −40°C to 85°C.

TLE2071I operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2071I			TLE2071AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±10 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C	30	40		30	40		V/μs
				Full range	24			24			
SR−	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	24			24			
t_s	Settling time	A_{VD} = −1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = −1, C_L = 25 pF	25°C	478	637		478	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

† Full range is −40°C to 85°C.

TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071M			TLE2071AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω,		25°C		0.34	4		0.3	2	mV
				Full range			9.2			7.2	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		3.2	29‡		3.2	29‡	µV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		5	100		5	100	pA
				Full range			20			20	nA
I_{IB}	Input bias current			25°C		15	175		15	175	pA
				Full range			60			60	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
				Full range	5 to −0.8			5 to −0.8			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA		25°C	3.8	4.1		3.8	4.1		V
				Full range	3.6			3.6			
		I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
				Full range	3.3			3.3			
		I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
				Full range	1.4			1.4			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA		25°C	−3.8	−4.2		−3.8	−4.2		V
				Full range	−3.6			−3.6			
		I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.3			−3.3			
		I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
				Full range	−1.4			−1.4			
A_{VD}	Large-signal differential voltage amplification	V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
				Full range	78			78			
			R_L = 2 kΩ	25°C	90	100		90	100		
				Full range	88			88			
			R_L = 10 kΩ	25°C	95	106		95	106		
				Full range	93			93			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		11			11		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
				Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

† Full range is −55°C to 125°C.
‡ *On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071M			TLE2071AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current	V_O = 0,	No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
				Full range			2.2			2.2	
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

† Full range is −55°C to 125°C.

TLE2071M operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2071M			TLE2071AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	20‡			20‡			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	20‡			20‡			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85‡		48	85‡	nV/√Hz
			f = 10 kHz			12	17‡		12	17‡	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is −55°C to 125°C.
‡ *On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071M			TLE2071AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		0.49	4		0.47	2	mV
				Full range			9.2			7.2	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		3.2	29*		3.2	29*	μV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		6	100		6	100	pA
				Full range			20			20	nA
I_{IB}	Input bias current			25°C		20	175		20	175	pA
				Full range			60			60	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	15 to −11	15 to −11.9		15 to −11	15 to −11.9		V
				Full range	15 to −10.9			15 to −10.9			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 μA		25°C	13.8	14.1		13.8	14.1		V
				Full range	13.6			13.6			
		I_O = −2 mA		25°C	13.5	13.9		13.5	13.9		
				Full range	13.3			13.3			
		I_O = −20 mA		25°C	11.5	12.3		11.5	12.3		
				Full range	11.4			11.4			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 μA		25°C	−13.8	−14.2		−13.8	−14.2		V
				Full range	−13.6			−13.6			
		I_O = 2 mA		25°C	−13.5	−14		−13.5	−14		
				Full range	−13.3			−13.3			
		I_O = 20 mA		25°C	−11.5	−12.4		−11.5	−12.4		
				Full range	−11.4			−11.4			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
				Full range	78			78			
			R_L = 2 kΩ	25°C	90	109		90	109		
				Full range	88			88			
			R_L = 10 kΩ	25°C	95	118		95	118		
				Full range	93			93			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		7.5			7.5		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
				Full range	78			78			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.
† Full range is −55°C to 125°C.

TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2071M			TLE2071AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current	V_O = 0,	No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
				Full range			2.2			2.2	
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	−30	−45		−30	−45		mA
			V_{ID} = −1 V		30	48		30	48		

† Full range is −55°C to 125°C.

TLE2071M operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2071M			TLE2071AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = 10 V, R_L = 2 kΩ, See Figure 1	A_{VD} = −1, C_L = 100 pF,	25°C	30	40		30	40		V/μs
				Full range	22			22			
SR−	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	22			22			
t_s	Settling time	A_{VD} = −1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85*		48	85*	nV/√Hz
			f = 10 kHz			12	17*		12	17*	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8*	10		8*	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = −1, C_L = 25 pF	25°C	478*	637		478*	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.
† Full range is −55°C to 125°C.

TLE2071Y electrical characteristics at $V_{CC\pm}$ = ±15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS			TLE2071Y			UNIT
					MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0,	V_O = 0,	R_S = 50 Ω		0.49	4	mV
I_{IO}	Input offset current	V_{IC} = 0,	V_O = 0,	See Figure 4		6	100	pA
I_{IB}	Input bias current					20	175	pA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω			15 to −11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA			13.8	14.1		V
		I_O = −2 mA			13.5	13.9		
		I_O = −20 mA			11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA			−13.8	−14.2		V
		I_O = 2 mA			−13.5	−14		
		I_O = 20 mA			−11.5	−12.4		
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V	R_L = 600 Ω		80	96		dB
			R_L = 2 kΩ		90	109		
			R_L = 10 kΩ		95	118		
r_i	Input resistance	V_{IC} = 0				10^{12}		Ω
c_i	Input capacitance	V_O = 0, See Figure 5	Common mode			7.5		pF
			Differential			2.5		
z_o	Open-loop output impedance	f = 1 MHz				80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, R_S = 50 Ω		V_O = 0,	80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, R_S = 50 Ω		V_O = 0,	82	99		dB
I_{CC}	Supply current	V_O = 0,	No load		1.35	1.7	2.2	mA
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V		−30	−45		mA
			V_{ID} = −1 V		30	48		

TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072C			TLE2072AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		0.9	6		0.65	3.5	mV
				Full range			7.8			5.3	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		2.3	25		2.3	25	µV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		5	100		5	100	pA
				Full range			1.4			1.4	nA
I_{IB}	Input bias current			25°C		15	175		15	175	pA
				Full range			5			5	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
				Full range	5 to −0.9			5 to −0.9			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA		25°C	3.8	4.1		3.8	4.1		V
				Full range	3.7			3.7			
		I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
				Full range	3.4			3.4			
		I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
				Full range	1.5			1.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA		25°C	−3.8	−4.2		−3.8	−4.2		V
				Full range	−3.7			−3.7			
		I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.4			−3.4			
		I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
				Full range	−1.5			−1.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	100		90	100		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	106		95	106		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		11			11		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
				Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

† Full range is 0°C to 70°C.

TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A	TLE2072C			TLE2072AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (both channels)	V_O = 0,	No load	25°C	2.7	2.9	3.9	2.7	2.9	3.9	mA
				Full range			3.9			3.9	
a_x	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

TLE2072C operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2072C			TLE2072AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	22			22			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	22			22			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is 0°C to 70°C.

TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072C			TLE2072AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		1.1	6		0.7	3.5	mV
				Full range			7.8			5.3	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		2.4	25		2.4	25	µV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		6	100		6	100	pA
				Full range			1.4			1.4	nA
I_{IB}	Input bias current			25°C		20	175		20	175	pA
				Full range			5			5	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	15 to −11	15 to −11.9		15 to −11	15 to −11.9		V
				Full range	15 to −10.9			15 to −10.9			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA		25°C	13.8	14.1		13.8	14.1		V
				Full range	13.6			13.6			
		I_O = −2 mA		25°C	13.5	13.9		13.5	13.9		
				Full range	13.4			13.4			
		I_O = −20 mA		25°C	11.5	12.3		11.5	12.3		
				Full range	11.5			11.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA		25°C	−13.8	−14.2		−13.8	−14.2		V
				Full range	−13.7			−13.7			
		I_O = 2 mA		25°C	−13.5	−14		−13.5	−14		
				Full range	−13.4			−13.4			
		I_O = 20 mA		25°C	−11.5	−12.4		−11.5	−12.4		
				Full range	−11.5			−11.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	109		90	109		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	118		95	118		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		7.5			7.5		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
				Full range	79			79			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	81			81			

† Full range is 0°C to 70°C.

TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A	TLE2072C			TLE2072AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (both channels)	V_O = 0,	No load	25°C	2.7	3.1	3.9	2.7	3.1	3.9	mA
				Full range			3.9			3.9	
a_x	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	−30	−45		−30	−45		mA
			V_{ID} = −1 V		30	48		30	48		

TLE2072C operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2072C			TLE2072AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = 10 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C	28	40		28	40		V/μs
				Full range	25			25			
SR−	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	25			25			
t_s	Settling time	A_{VD} = −1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = −1, C_L = 25 pF	25°C	478	637		478	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

† Full range is 0°C to 70°C.

TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072I			TLE2072AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω,		25°C		0.9	6		0.65	3.5	mV
				Full range			9.1			6.4	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		2.4	25		2.4	25	μV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		5	100		5	100	pA
				Full range			5			5	nA
I_{IB}	Input bias current			25°C		15	175		15	175	pA
				Full range			10			10	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
				Full range	5 to −0.8			5 to −0.8			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 μA		25°C	3.8	4.1		3.8	4.1		V
				Full range	3.7			3.7			
		I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
				Full range	3.4			3.4			
		I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
				Full range	1.5			1.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 μA		25°C	−3.8	−4.2		−3.8	−4.2		V
				Full range	−3.7			−3.7			
		I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.4			−3.4			
		I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
				Full range	−1.5			−1.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	100		90	100		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	106		95	106		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		11			11		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
				Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

† Full range is −40°C to 85°C.

TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A	TLE2072I			TLE2072AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (both channels)	V_O = 0,	No load	25°C	2.7	2.9	3.9	2.7	2.9	3.9	mA
				Full range			3.9			3.9	
a_x	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

TLE2072I operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2072I			TLE2072AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	20			20			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	20			20			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is 40°C to 85°C.

TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072I			TLE2072AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω,		25°C		1.1	6		0.7	3.5	mV
				Full range			9.1			6.4	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		2.4	25		2.4	25	µV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		6	100		6	100	pA
				Full range			5			5	nA
I_{IB}	Input bias current			25°C		20	175		20	175	pA
				Full range			10			10	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	15 to −11	15 to −11.9		15 to −11	15 to −11.9		V
				Full range	15 to −10.8			15 to −10.8			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA		25°C	13.8	14.1		13.8	14.1		V
				Full range	13.7			13.7			
		I_O = −2 mA		25°C	13.5	13.9		13.5	13.9		
				Full range	13.4			13.4			
		I_O = −20 mA		25°C	11.5	12.3		11.5	12.3		
				Full range	11.5			11.5			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA		25°C	−13.8	−14.2		−13.8	−14.2		V
				Full range	−13.7			−13.7			
		I_O = 2 mA		25°C	−13.5	−14		−13.5	−14		
				Full range	−13.4			−13.4			
		I_O = 20 mA		25°C	−11.5	−12.4		−11.5	−12.4		
				Full range	−11.5			−11.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
				Full range	79			79			
			R_L = 2 kΩ	25°C	90	109		90	109		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	118		95	118		
				Full range	94			94			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		7.5			7.5		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
				Full range	79			79			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

† Full range is −40°C to 85°C.

TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A	TLE2072I			TLE2072AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (both channels)	V_O = 0,	No load	25°C	2.7	3.1	3.9	2.7	3.1	3.9	mA
				Full range			3.9			3.9	
a_x	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	–30	–45		–30	–45		mA
			V_{ID} = –1 V		30	48		30	48		

TLE2072I operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2072I			TLE2072AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±10 V, A_{VD} = –1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C	28	40		28	40		V/μs
				Full range	22			22			
SR–	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	22			22			
t_s	Settling time	A_{VD} = –1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 0 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = –1, C_L = 25 pF	25°C	478	637		478	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

† Full range is –40°C to 85°C.

TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072M			TLE2072AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω,		25°C		0.9	6		0.65	3.5	mV
				Full range			10.5			8	
α_{VIO}	Temperature coefficient of input offset voltage			Full range		2.3	25*		2.3	25*	μV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		5	100		5	100	pA
				Full range			20			20	nA
I_{IB}	Input bias current			25°C		15	175		15	175	pA
				Full range			60			60	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
				Full range	5 to −0.8			5 to −0.8			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 μA		25°C	3.8	4.1		3.8	4.1		V
				Full range	3.6			3.6			
		I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
				Full range	3.3			3.3			
		I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
				Full range	1.4			1.4			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 μA		25°C	−3.8	−4.2		−3.8	−4.2		V
				Full range	−3.6			−3.6			
		I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.3			−3.3			
		I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
				Full range	−1.4			−1.4			
A_{VD}	Large-signal differential voltage amplification	V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
				Full range	78			78			
			R_L = 2 kΩ	25°C	90	100		90	100		
				Full range	88			88			
			R_L = 10 kΩ	25°C	95	106		95	106		
				Full range	93			93			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		11			11		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
				Full range	68			68			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.
† Full range is −55°C to 125°C.

TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072M			TLE2072AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0,	R_S = 50 Ω	Full range	80			80			dB
I_{CC}	Supply current (both channels)	V_O = 0,	No load	25°C	2.7	2.9	3.6	2.7	2.9	3.6	mA
				Full range			3.6			3.6	
a_x	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

† Full range is −55°C to 125°C.

TLE2072M operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2072M			TLE2072AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	18*			18*			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	18*			18*			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85*		48	85*	nV/√Hz
			f = 10 kHz			12	17*		12	17*	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.
† Full range is −55°C to 125°C.

TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072M			TLE2072AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		1.1	6		0.7	3.5	mV
				Full range			10.5			8	
α_{VIO}	Temperature coefficient of input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		Full range		2.4	25*		2.4	25*	µV/°C
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4		25°C		6	100		6	100	pA
				Full range			20			20	nA
I_{IB}	Input bias current			25°C		20	175		20	175	pA
				Full range			60			60	nA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		25°C	15 to −11	15 to −11.9		15 to −11	15 to −11.9		V
				Full range	15 to −10.8			15 to −10.8			
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 µA		25°C	13.8	14.1		13.8	14.1		V
				Full range	13.6			13.6			
		I_O = −2 mA		25°C	13.5	13.9		13.5	13.9		
				Full range	13.3			13.3			
		I_O = −20 mA		25°C	11.5	12.3		11.5	12.3		
				Full range	11.4			11.4			
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 µA		25°C	−13.8	−14.2		−13.8	−14.2		V
				Full range	−13.6			−13.6			
		I_O = 2 mA		25°C	−13.5	−14		−13.5	−14		
				Full range	−13.3			−13.3			
		I_O = 20 mA		25°C	−11.5	−12.4		−11.5	−12.4		
				Full range	−11.4			−11.4			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
				Full range	78			78			
			R_L = 2 kΩ	25°C	90	109		90	109		
				Full range	89			89			
			R_L = 10 kΩ	25°C	95	118		95	118		
				Full range	93			93			
r_i	Input resistance	V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode	25°C		7.5			7.5		pF
			Differential	25°C		2.5			2.5		
z_o	Open-loop output impedance	f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
				Full range	78			78			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
				Full range	80			80			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.
† Full range is −55°C to 125°C.

TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLE2072M			TLE2072AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (both channels)	V_O = 0,	No load	25°C	2.7	3.1	3.6	2.7	3.1	3.6	mA
				Full range			3.6			3.6	
a_x	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	–30	–45		–30	–45		mA
			V_{ID} = –1 V		30	48		30	48		

† Full range is –55°C to 125°C.

TLE2072M operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2072M			TLE2072AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = 10 V, R_L = 2 kΩ, See Figure 1	A_{VD} = –1, C_L = 100 pF,	25°C	28	40		28	40		V/μs
				Full range	20			20			
SR–	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	20			20			
t_s	Settling time	A_{VD} = –1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85*		48	85*	nV/√Hz
			f = 10 kHz			12	17*		12	17*	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8*	10		8*	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = –1, C_L = 25 pF	25°C	478*	637		478*	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.
† Full range is –55°C to 125°C.

TLE2072Y electrical characteristics at $V_{CC\pm}$ = ±15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TLE2072Y			UNIT
				MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω			1.1	6	mV
I_{IO}	Input offset current	V_{IC} = 0, V_O = 0, See Figure 4			6	100	pA
I_{IB}	Input bias current				20	175	pA
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω		15 to −11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing	I_O = −200 μA		13.8	14.1		V
		I_O = −2 mA		13.5	13.9		
		I_O = −20 mA		11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing	I_O = 200 μA		−13.8	−14.2		V
		I_O = 2 mA		−13.5	−14		
		I_O = 20 mA		−11.5	−12.4		
A_{VD}	Large-signal differential voltage amplification	V_O = ± 10 V	R_L = 600 Ω	80	96		dB
			R_L = 2 kΩ	90	109		
			R_L = 10 kΩ	95	118		
r_i	Input resistance	V_{IC} = 0			10^{12}		Ω
c_i	Input capacitance	V_{IC} = 0, See Figure 5	Common mode		7.5		pF
			Differential		2.5		
z_o	Open-loop output impedance	f = 1 MHz			80		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		82	99		dB
I_{CC}	Supply current (both channels)	V_O = 0, No load		2.7	3.1	3.9	mA
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	−30	−45		mA
			V_{ID} = −1 V	30	48		

TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T_A†	TLE2074C			TLE2074AC			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage		V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		−1.6	5		−0.5	3	mV
					Full range			7.1			5.1	
α_{VIO}	Temperature coefficient of input offset voltage				Full range		10.1	30		10.1	30	µV/°C
I_{IO}	Input offset current		V_{IC} = 0, V_O = 0, See Figure 4		25°C		15	100		15	100	pA
					Full range			1400			1400	
I_{IB}	Input bias current				25°C		20	175		20	175	pA
					Full range			5000			5000	
V_{ICR}	Common-mode input voltage range		R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
					Full range	5 to −0.9			5 to −0.9			
V_{OM+}	Maximum positive peak output voltage swing		I_O = −200 µA		25°C	3.8	4.1		3.8	4.1		V
					Full range	3.7			3.7			
			I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
					Full range	3.4			3.4			
			I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
					Full range	1.5			1.5			
V_{OM-}	Maximum negative peak output voltage swing		I_O = 200 µA		25°C	−3.8	−4.2		−3.8	−4.2		V
					Full range	−3.7			−3.7			
			I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
					Full range	−3.4			−3.4			
			I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
					Full range	−1.5			−1.5			
A_{VD}	Large-signal differential voltage amplification		V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
					Full range	79			79			
				R_L = 2 kΩ	25°C	90	100		90	100		
					Full range	89			89			
				R_L = 10 kΩ	25°C	95	106		95	106		
					Full range	94			94			
r_i	Input resistance		V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	Common mode	V_{IC} = 0, See Figure 5		25°C		11			11		pF
		Differential			25°C		2.5			2.5		
z_o	Open-loop output impedance		f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio		V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
					Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)		$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
					Full range	80			80			

† Full range is 0°C to 70°C.

TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2074C			TLE2074AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (four amplifiers)	V_O = 0,	No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA
				Full range			7.5			7.5	
	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

† Full range is 0°C to 70°C.

TLE2074C operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2074C			TLE2074AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	22			22			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	22			22			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is 0°C to 70°C.

TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T_A†	TLE2074C			TLE2074AC			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage		V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		–1.6	5		–0.5	3	mV
					Full range			7.1			5.1	
α_{VIO}	Temperature coefficient of input offset voltage				Full range		10.1	30		10.1	30	μV/°C
I_{IO}	Input offset current		V_{IC} = 0, V_O = 0, See Figure 4		25°C		15	100		15	100	pA
					Full range			1400			1400	
I_{IB}	Input bias current				25°C		25	175		25	175	pA
					Full range			5000			5000	
V_{ICR}	Common-mode input voltage range		R_S = 50 Ω		25°C	15 to –11	15 to –11.9		15 to –11	15 to –11.9		V
					Full range	15 to –10.9			15 to –10.9			
V_{OM+}	Maximum positive peak output voltage swing		I_O = –200 μA		25°C	13.8	14.1		13.8	14.1		V
					Full range	13.7			13.7			
			I_O = –2 mA		25°C	13.5	13.9		13.5	13.9		
					Full range	13.4			13.4			
			I_O = –20 mA		25°C	11.5	12.3		11.5	12.3		
					Full range	11.5			11.5			
V_{OM-}	Maximum negative peak output voltage swing		I_O = 200 μA		25°C	–13.8	–14.2		–13.8	–14.2		V
					Full range	–13.7			–13.7			
			I_O = 2 mA		25°C	–13.7	–14		–13.7	–14		
					Full range	–13.6			–13.6			
			I_O = 20 mA		25°C	–11.5	–12.4		–11.5	–12.4		
					Full range	–11.5			–11.5			
A_{VD}	Large-signal differential voltage amplification		V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
					Full range	79			79			
				R_L = 2 kΩ	25°C	90	109		90	109		
					Full range	89			89			
				R_L = 10 kΩ	25°C	95	118		95	118		
					Full range	94			94			
r_i	Input resistance		V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	Common mode	V_{IC} = 0, See Figure 5		25°C		7.5			7.5		pF
		Differential			25°C		2.5			2.5		
z_o	Open-loop output impedance		f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio		V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
					Full range	79			79			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)		$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
					Full range	81			81			

† Full range is 0°C to 70°C.

TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2074C			TLE2074AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (four amplifiers)	V_O = 0,	No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
				Full range			7.5			7.5	
	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	–30	–45		–30	–45		mA
			V_{ID} = –1 V		30	48		30	48		

† Full range is 0°C to 70°C.

TLE2074C operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2074C			TLE2074AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = 10 V, R_L = 2 kΩ, See Figure 1	A_{VD} = –1, C_L = 100 pF,	25°C	25	40		25	40		V/μs
				Full range	22			22			
SR–	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	25			25			
t_s	Settling time	A_{VD} = –1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = –1, C_L = 25 pF	25°C	478	637		478	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

† Full range is 0°C to 70°C.

TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T_A†	TLE2074I			TLE2074AI			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage		V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		−1.6	5		−0.5	3	mV
					Full range			9			7	
α_{VIO}	Temperature coefficient of input offset voltage				Full range		10.1	30		10.1	30	μV/°C
I_{IO}	Input offset current		V_{IC} = 0, V_O = 0, See Figure 4		25°C		15	100		15	100	pA
					Full range			5			5	nA
I_{IB}	Input bias current				25°C		20	175		20	175	pA
					Full range			10			10	nA
V_{ICR}	Common-mode input voltage range		R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
					Full range	5 to −0.8			5 to −0.8			
V_{OM+}	Maximum positive peak output voltage swing		I_O = −200 μA		25°C	3.8	4.1		3.8	4.1		V
					Full range	3.7			3.7			
			I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
					Full range	3.4			3.4			
			I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
					Full range	1.5			1.5			
V_{OM-}	Maximum negative peak output voltage swing		I_O = 200 μA		25°C	−3.8	−4.2		−3.8	−4.2		V
					Full range	−3.7			−3.7			
			I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
					Full range	−3.4			−3.4			
			I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
					Full range	−1.5			−1.5			
A_{VD}	Large-signal differential voltage amplification		V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
					Full range	79			79			
				R_L = 2 kΩ	25°C	90	100		90	100		
					Full range	89			89			
				R_L = 10 kΩ	25°C	95	106		95	106		
					Full range	94			94			
r_i	Input resistance		V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	Common mode	V_{IC} = 0, See Figure 5		25°C		11			11		pF
		Differential			25°C		2.5			2.5		
z_o	Open-loop output impedance		f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio		V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
					Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)		$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
					Full range	80			80			

† Full range is −40°C to 85°C.

TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2074I			TLE2074AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (four amplifiers)	V_O = 0,	No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA
				Full range			7.5			7.5	
	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

† Full range is −40°C to 85°C.

TLE2074I operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2074I			TLE2074AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	20			20			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	20			20			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is −40°C to 85°C.

TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T_A†	TLE2074I			TLE2074AI			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage		V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		–1.6	5		–0.5	3	mV
					Full range			9			7	
α_{VIO}	Temperature coefficient of input offset voltage				Full range		10.1	30		10.1	30	µV/°C
I_{IO}	Input offset current		V_{IC} = 0, V_O = 0, See Figure 4		25°C		15	100		15	100	pA
					Full range			5			5	nA
I_{IB}	Input bias current				25°C		25	175		25	175	pA
					Full range			10			10	nA
V_{ICR}	Common-mode input voltage range		R_S = 50 Ω		25°C	15 to –11	15 to –11.9		15 to –11	15 to –11.9		V
					Full range	15 to –10.8			15 to –10.8			
V_{OM+}	Maximum positive peak output voltage swing		I_O = –200 µA		25°C	13.8	14.1		13.8	14.1		V
					Full range	13.7			13.7			
			I_O = –2 mA		25°C	13.5	13.9		13.5	13.9		
					Full range	13.4			13.4			
			I_O = –20 mA		25°C	11.5	12.3		11.5	12.3		
					Full range	11.5			11.5			
V_{OM-}	Maximum negative peak output voltage swing		I_O = 200 µA		25°C	–13.8	–14.2		–13.8	–14.2		V
					Full range	–13.7			–13.7			
			I_O = 2 mA		25°C	–13.5	–14		–13.5	–14		
					Full range	–13.4			–13.4			
			I_O = 20 mA		25°C	–11.5	–12.4		–11.5	–12.4		
					Full range	–11.5			–11.5			
A_{VD}	Large-signal differential voltage amplification		V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
					Full range	79			79			
				R_L = 2 kΩ	25°C	90	109		90	109		
					Full range	89			89			
				R_L = 10 kΩ	25°C	95	118		95	118		
					Full range	94			94			
r_i	Input resistance		V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	Common mode	V_{IC} = 0, See Figure 5		25°C		7.5			7.5		pF
		Differential			25°C		2.5			2.5		
z_o	Open-loop output impedance		f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio		V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
					Full range	79			79			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)		$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
					Full range	80			80			

† Full range is –40°C to 85°C.

TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2074I			TLE2074AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (four amplifiers)	V_O = 0,	No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
				Full range			7.5			7.5	
	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	–30	–45		–30	–45		mA
			V_{ID} = –1 V		30	48		30	48		

† Full range is –40°C to 85°C.

TLE2074I operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2074I			TLE2074AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±10 V, A_{VD} = –1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C	25	40		25	40		V/μs
				Full range	19			19			
SR–	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	22			22			
t_s	Settling time	A_{VD} = –1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85		48	85	nV/√Hz
			f = 10 kHz			12	17		12	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = –1, C_L = 25 pF	25°C	478	637		478	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

† Full range is –40°C to 85°C.

TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T_A†	TLE2074M			TLE2074AM			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage		V_{IC} = 0, V_O = 0, R_S = 50Ω		25°C		−1.6	5		−0.5	3	mV
					Full range			10.5			8.5	
α_{VIO}	Temperature coefficient of input offset voltage				Full range		10.1	30‡		10.1	30‡	µV/°C
I_{IO}	Input offset current		V_{IC} = 0, V_O = 0, See Figure 4		25°C		15	100		15	100	pA
					Full range			20			20	nA
I_{IB}	Input bias current				25°C		20	175		20	175	pA
					Full range			60			60	nA
V_{ICR}	Common-mode input voltage range		R_S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V
					Full range	5 to −0.8			5 to −0.8			
V_{OM+}	Maximum positive peak output voltage swing		I_O = −200 µA		25°C	3.8	4.1		3.8	4.1		V
					Full range	3.6			3.6			
			I_O = −2 mA		25°C	3.5	3.9		3.5	3.9		
					Full range	3.3			3.3			
			I_O = −20 mA		25°C	1.5	2.3		1.5	2.3		
					Full range	1.4			1.4			
V_{OM-}	Maximum negative peak output voltage swing		I_O = 200 µA		25°C	−3.8	−4.2		−3.8	−4.2		V
					Full range	−3.6			−3.6			
			I_O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1		
					Full range	−3.3			−3.3			
			I_O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4		
					Full range	−1.4			−1.4			
A_{VD}	Large-signal differential voltage amplification		V_O = ±2.3 V	R_L = 600 Ω	25°C	80	91		80	91		dB
					Full range	78			78			
				R_L = 2 kΩ	25°C	90	100		90	100		
					Full range	88			88			
				R_L = 10 kΩ	25°C	95	106		95	106		
					Full range	93			93			
r_i	Input resistance		V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	Common mode	V_{IC} = 0, See Figure 5		25°C		11			11		pF
		Differential			25°C		2.5			2.5		
z_o	Open-loop output impedance		f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio		V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	70	89		70	89		dB
					Full range	68			68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)		$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
					Full range	80			80			

† Full range is −55°C to 125°C.
‡ On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2074M			TLE2074AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (four amplifiers)	V_O = 0,	No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA
				Full range			7.5			7.5	
	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C		−35			−35		mA
			V_{ID} = −1 V			45			45		

† Full range is −55°C to 125°C.

TLE2074M operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLE2074M			TLE2074AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = ±2.3 V, A_{VD} = −1, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	25°C		35			35		V/μs
				Full range	18‡			18‡			
SR−	Negative slew rate			25°C		38			38		V/μs
				Full range	18‡			18‡			
t_s	Settling time	A_{VD} = −1, 2-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.25			0.25		μs
			To 1 mV			0.4			0.4		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85‡		48	85‡	nV/√Hz
			f = 10 kHz			12	17‡		12	17‡	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 5 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.013%			0.013%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		9.4			9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4 V, R_L = 2 kΩ,	A_{VD} = −1, C_L = 25 pF	25°C		2.8			2.8		MHz
f_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		56°			56°		

† Full range is −55°C to 125°C.
‡ On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T_A†	TLE2074M			TLE2074AM			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage		V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		–1.6	5		–0.5	3	mV
					Full range			10.5			8.5	
α_{VIO}	Temperature coefficient of input offset voltage				Full range		10.1	30‡		10.1	30‡	µV/°C
I_{IO}	Input offset current		V_{IC} = 0, V_O = 0, See Figure 4		25°C		15	100		15	100	pA
					Full range			20			20	nA
I_{IB}	Input bias current				25°C		25	175		25	175	pA
					Full range			60			60	nA
V_{ICR}	Common-mode input voltage range		R_S = 50 Ω		25°C	15 to –11	15 to –11.9		15 to –11	15 to –11.9		V
					Full range	15 to –10.8			15 to –10.8			
V_{OM+}	Maximum positive peak output voltage swing		I_O = –200 µA		25°C	13.8	14.1		13.8	14.1		V
					Full range	13.6			13.6			
			I_O = –2 mA		25°C	13.5	13.9		13.5	13.9		
					Full range	13.3			13.3			
			I_O = –20 mA		25°C	11.5	12.3		11.5	12.3		
					Full range	11.4			11.4			
V_{OM-}	Maximum negative peak output voltage swing		I_O = 200 µA		25°C	–13.8	–14.2		–13.8	–14.2		V
					Full range	–13.6			–13.6			
			I_O = 2 mA		25°C	–13.5	–14		–13.5	–14		
					Full range	–13.3			–13.3			
			I_O = 20 mA		25°C	–11.5	–12.4		–11.5	–12.4		
					Full range	–11.4			–11.4			
A_{VD}	Large-signal differential voltage amplification		V_O = ±10 V	R_L = 600 Ω	25°C	80	96		80	96		dB
					Full range	78			78			
				R_L = 2 kΩ	25°C	90	109		90	109		
					Full range	88			88			
				R_L = 10 kΩ	25°C	95	118		95	118		
					Full range	93			93			
r_i	Input resistance		V_{IC} = 0		25°C		10^{12}			10^{12}		Ω
c_i	Input capacitance	Common mode	V_{IC} = 0, See Figure 5		25°C		7.5			7.5		pF
		Differential			25°C		2.5			2.5		
z_o	Open-loop output impedance		f = 1 MHz		25°C		80			80		Ω
CMRR	Common-mode rejection ratio		V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω		25°C	80	98		80	98		dB
					Full range	78			78			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)		$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0, R_S = 50 Ω		25°C	82	99		82	99		dB
					Full range	80			80			

† Full range is –55°C to 125°C.
‡ On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLE2074M			TLE2074AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (four amplifiers)	V_O = 0,	No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
				Full range			7.5			7.5	
	Crosstalk attenuation	V_{IC} = 0,	R_L = 2 kΩ	25°C		120			120		dB
I_{OS}	Short-circuit output current	V_O = 0	V_{ID} = 1 V	25°C	–30	–45		–30	–45		mA
			V_{ID} = –1 V		30	48		30	48		

† Full range is –55°C to 125°C.

TLE2074M operating characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V

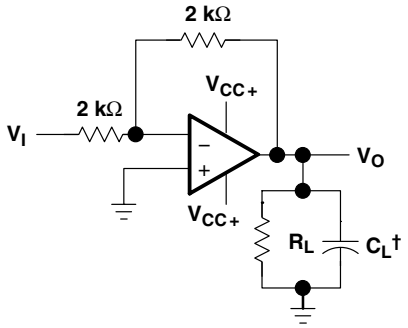
PARAMETER		TEST CONDITIONS		T_A†	TLE2074M			TLE2074AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)}$ = 10 V, R_L = 2 kΩ, See Figure 1	A_{VD} = –1, C_L = 100 pF,	25°C	25	40		25	40		V/μs
				Full range	17			17			
SR–	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	20			20			
t_s	Settling time	A_{VD} = –1, 10-V step, R_L = 1 kΩ, C_L = 100 pF	To 10 mV	25°C		0.4			0.4		μs
			To 1 mV			1.5			1.5		
V_n	Equivalent input noise voltage	R_S = 20 Ω, See Figure 3	f = 10 Hz	25°C		48	85‡		48	85‡	nV/√Hz
			f = 10 kHz			12	17‡		12	17‡	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C		6			6		μV
			f = 0.1 Hz to 10 Hz			0.6			0.6		
I_n	Equivalent input noise current	V_{IC} = 0,	f = 10 kHz	25°C		2.8			2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 20 V, f = 1 kHz, R_S = 25 Ω	A_{VD} = 10, R_L = 2 kΩ,	25°C		0.008%			0.008%		
B_1	Unity-gain bandwidth	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C	8‡	10		8‡	10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 20 V, R_L = 2 kΩ,	A_{VD} = –1, C_L = 25 pF	25°C	478‡	637		478‡	637		kHz
ϕ_m	Phase margin at unity gain	V_I = 10 mV, C_L = 25 pF,	R_L = 2 kΩ, See Figure 2	25°C		57°			57°		

† Full range is –55°C to 125°C.
‡ On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

TLE2074Y electrical characteristics at $V_{CC\pm}$ = ±15 V, T_A = 25°C (unless otherwise noted)

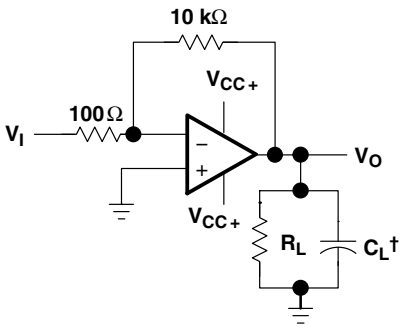
PARAMETER			TEST CONDITIONS		TLE2074Y MIN	TLE2074Y TYP	TLE2074Y MAX	UNIT
V_{IO}	Input offset voltage		V_{IC} = 0, R_S = 50 Ω	V_O = 0,			5	mV
I_{IO}	Input offset current		V_{IC} = 0, See Figure 4	V_O = 0,		15	100	pA
I_{IB}	Input bias current					25	175	pA
V_{ICR}	Common-mode input voltage range		R_S = 50 Ω		15 to −11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing		I_O = −200 μA		13.8	14.1		V
			I_O = −2 mA		13.5	13.9		
			I_O = −20 mA		11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing		I_O = 200 μA		−13.8	−14.2		V
			I_O = 2 mA		−13.5	−14		
			I_O = 20 mA		−11.5	−12.4		
A_{VD}	Large-signal differential voltage amplification		V_O = ±10 V	R_L = 600 Ω	80	96		dB
				R_L = 2 kΩ	90	109		
				R_L = 10 kΩ	95	118		
r_i	Input resistance		V_{IC} = 0			10^{12}		Ω
c_i	Input capacitance	Common mode	V_O = 0, See Figure 5			7.5		pF
		Differential				2.5		
z_o	Open-loop output impedance		f = 1 MHz			80		Ω
CMRR	Common-mode rejection ratio		V_{IC} = V_{ICR}min, R_S = 50 Ω	V_O = 0,	80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)		$V_{CC\pm}$ = ±5 V to ±15 V, V_O = 0,	R_S = 50 Ω	82	99		dB
I_{CC}	Supply current (four amplifiers)		V_O = 0,	No load	5.2	6.5	7.5	mA
I_{OS}	Short-circuit output current		V_O = 0	V_{ID} = 1 V	−30	−45		mA
				V_{ID} = −1 V	30	48		

PARAMETER MEASUREMENT INFORMATION



† Includes fixture capacitance

Figure 1. Slew-Rate Test Circuit



† Includes fixture capacitance

Figure 2. Unity-Gain Bandwidth and Phase-Margin Test Circuit

PARAMETER MEASUREMENT INFORMATION

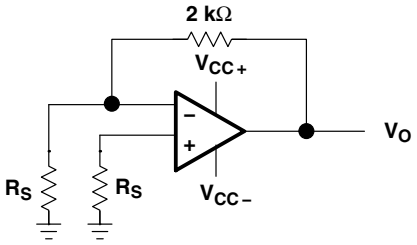


Figure 3. Noise-Voltage Test Circuit

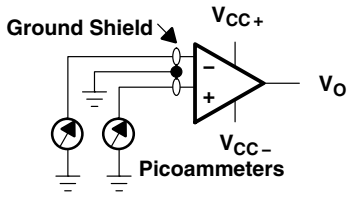


Figure 4. Input-Bias and Offset-Current Test Circuit

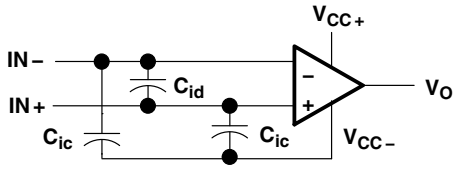


Figure 5. Internal Input Capacitance

typical values

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

input bias and offset current

At the picoampere bias current level typical of the TLE207x and TLE207xA, accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied but with no device in the socket. The device is then inserted in the socket and a second test is performed that measures both the socket leakage and the device input bias current. The two measurements are then subtracted algebraically to determine the bias current of the device.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	6, 7, 8
α_{VIO}	Temperature coefficient of input offset voltage	Distribution	9, 10, 11
I_{IO}	Input offset current	vs Free-air temperature	12, 13
I_{IB}	Input bias current	vs Free-air temperature vs Total supply voltage	12, 13 14
V_{ICR}	Common-mode input voltage range	vs Free-air temperature	15
V_O	Output voltage	vs Differential input voltage	16, 17
V_{OM+}	Maximum positive peak output voltage	vs Output current	18
V_{OM-}	Maximum negative peak output voltage	vs Output current	19
V_{OM}	Maximum peak output voltage	vs Free-air temperature vs Supply voltage	20, 21 22
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	23
V_O	Output voltage	vs Settling time	24
A_{VD}	Large-signal differential voltage amplification	vs Load resistance vs Free-air temperature	25 26, 27
A_{VD}	Small-signal differential voltage amplification	vs Frequency	28, 29
CMRR	Common-mode rejection ratio	vs Frequency vs Free-air temperature	30 31
k_{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature	32 33
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature vs Differential input voltage	34, 35, 36 37, 38, 39 40 – 45
I_{OS}	Short-circuit output current	vs Supply voltage vs Elapsed time vs Free-air temperature	46 47 48
SR	Slew rate	vs Free-air temperature vs Load resistance vs Differential input voltage	49, 50 51 52
V_n	Equivalent Input noise voltage (spectral density)	vs Frequency	53
V_n	Input referred noise voltage	vs Noise bandwidth Over a 10-second time interval	54 55
	Third-octave spectral noise density	vs Frequency bands	56
THD + N	Total harmonic distortion plus noise	vs Frequency	57, 58
B_1	Unity-gain bandwidth	vs Load capacitance	59
	Gain-bandwidth product	vs Free-air temperature vs Supply voltage	60 61
	Gain margin	vs Load capacitance	62
ϕ_m	Phase margin	vs Free-air temperature vs Supply voltage vs Load capacitance	63 64 65
	Phase shift	vs Frequency	28, 29
	Noninverting large-signal pulse response	vs Time	66
	Small-signal pulse response	vs Time	67
z_o	Closed-loop output impedance	vs Frequency	68
	Crosstalk attenuation	vs Frequency	69

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLE2071 INPUT OFFSET VOLTAGE

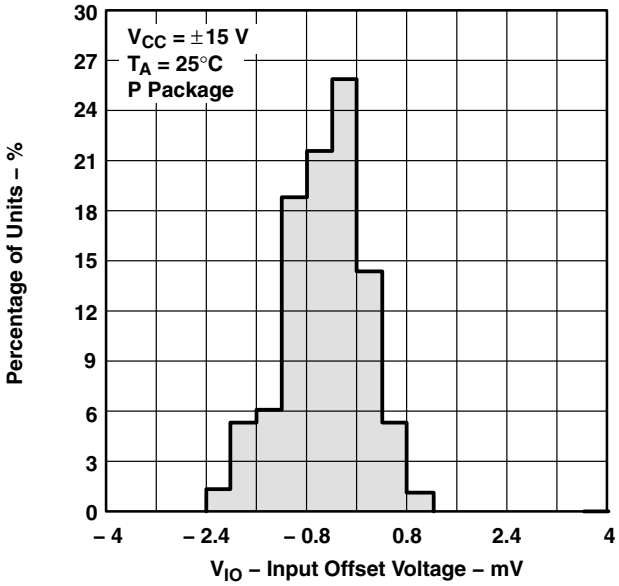


Figure 6

DISTRIBUTION OF TLE2072 INPUT OFFSET VOLTAGE

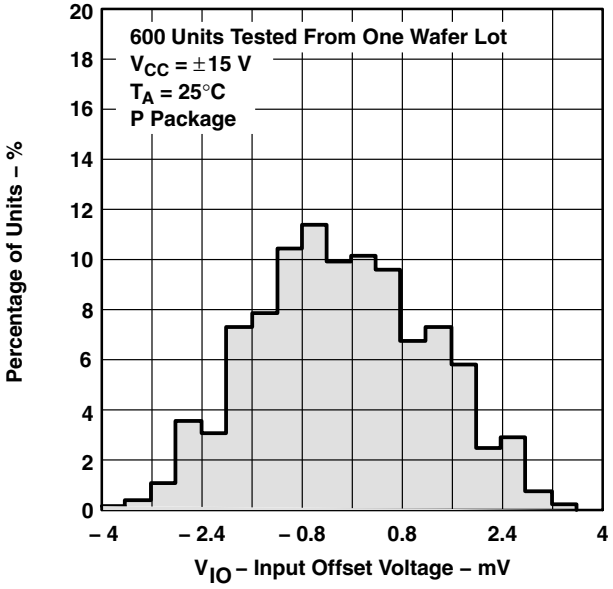


Figure 7

DISTRIBUTION OF TLE2074 INPUT OFFSET VOLTAGE

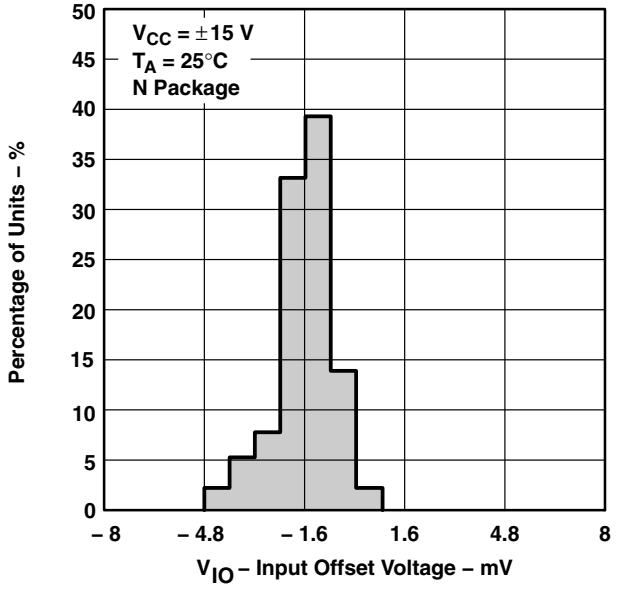


Figure 8

DISTRIBUTION OF TLE2071 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

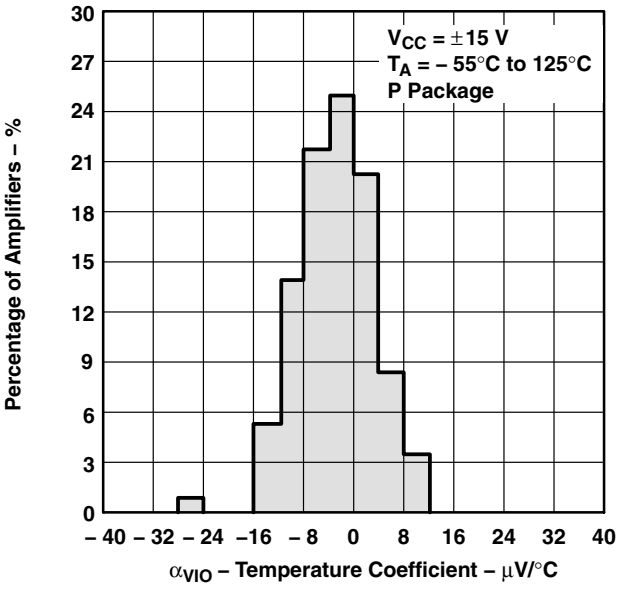


Figure 9

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLE2072 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

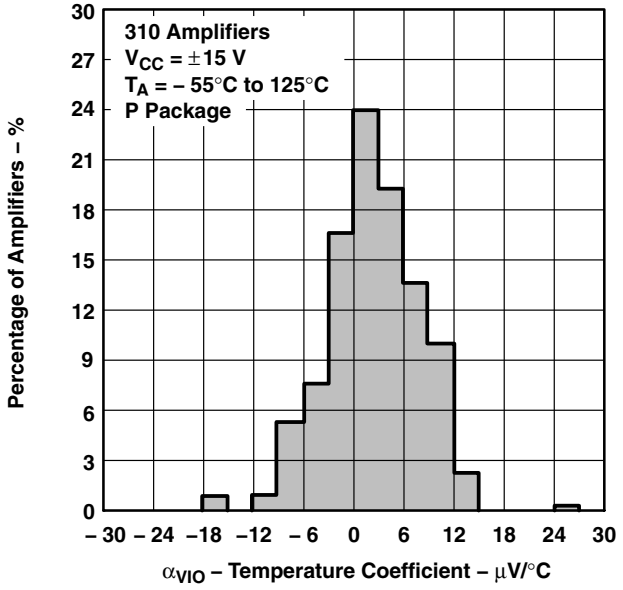


Figure 10

DISTRIBUTION OF TLE2074 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

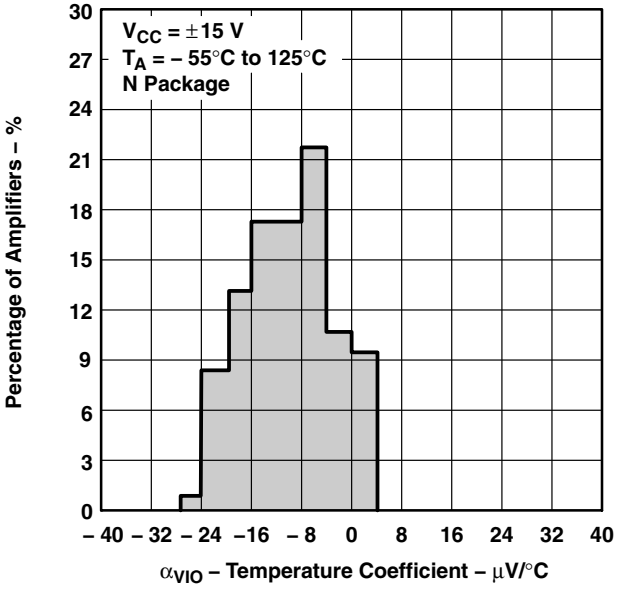


Figure 11

INPUT BIAS CURRENT AND INPUT OFFSET CURRENT† vs FREE-AIR TEMPERATURE

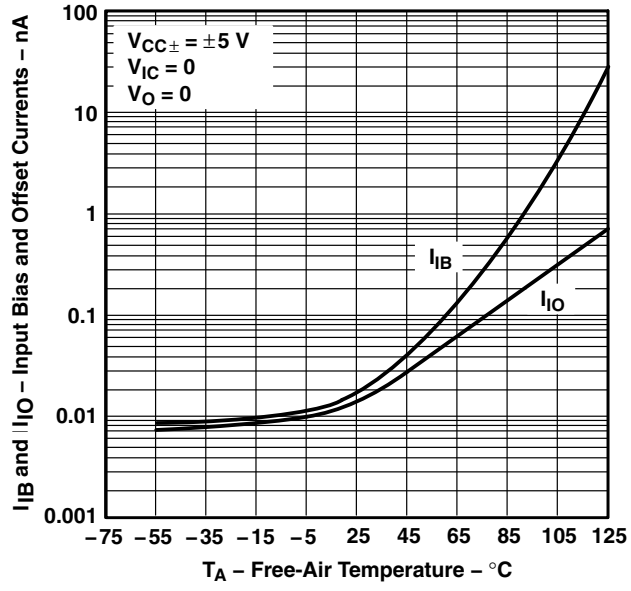


Figure 12

INPUT BIAS CURRENT AND INPUT OFFSET CURRENT† vs FREE-AIR TEMPERATURE

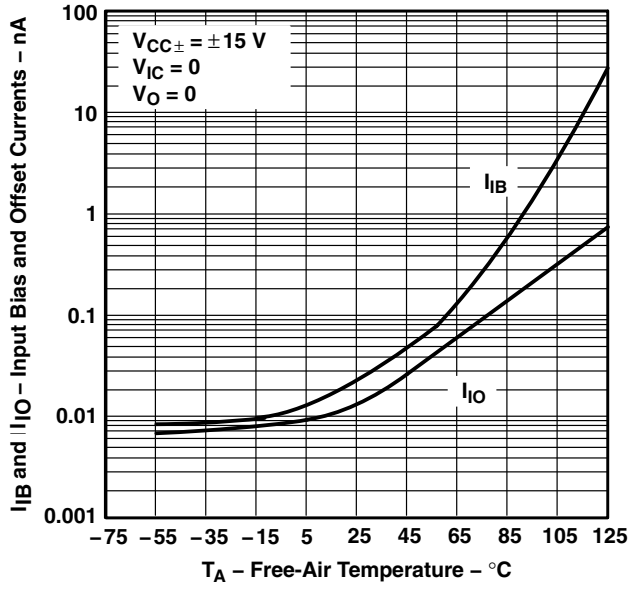


Figure 13

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

INPUT BIAS CURRENT vs TOTAL SUPPLY VOLTAGE

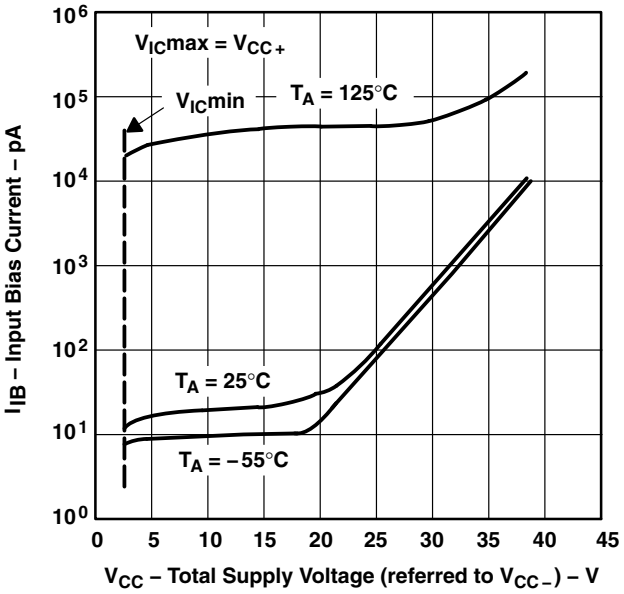


Figure 14

COMMON-MODE INPUT VOLTAGE RANGE† vs FREE-AIR TEMPERATURE

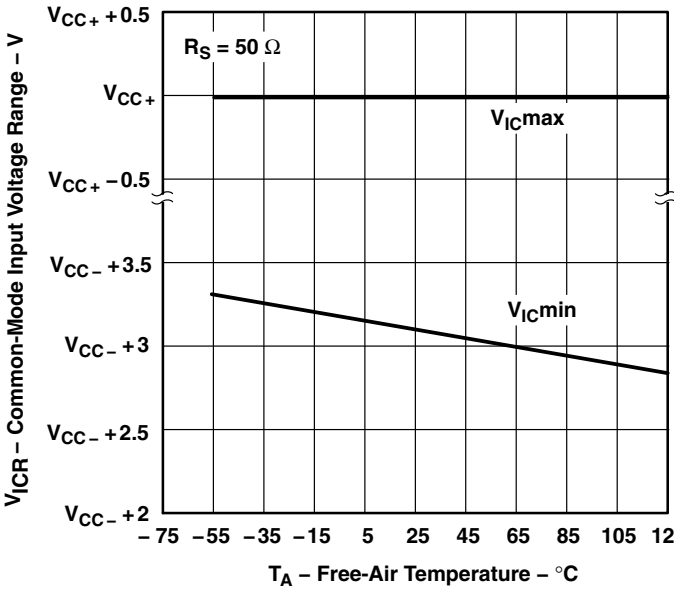


Figure 15

OUTPUT VOLTAGE vs DIFFERENTIAL INPUT VOLTAGE

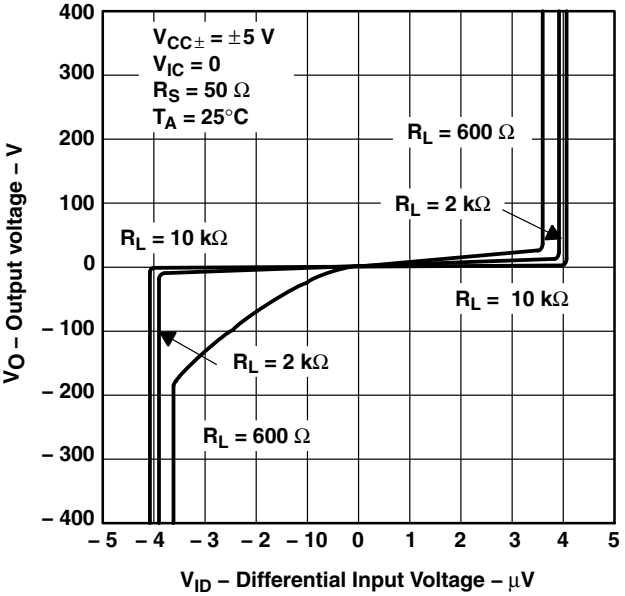


Figure 16

OUTPUT VOLTAGE vs DIFFERENTIAL INPUT VOLTAGE

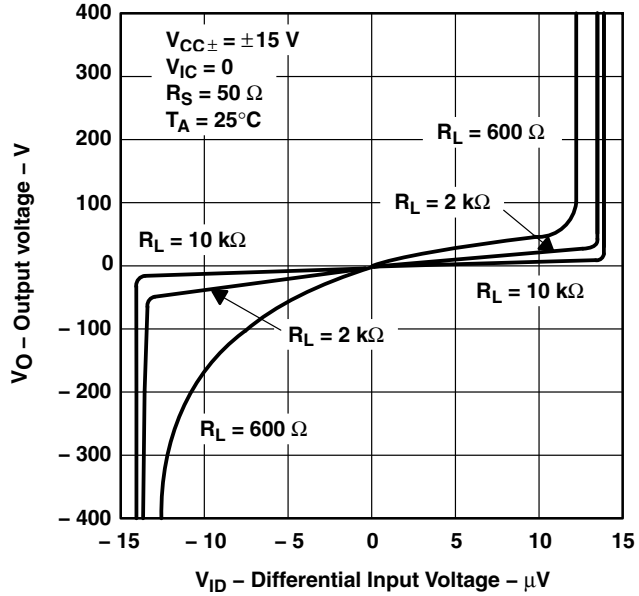


Figure 17

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE† vs OUTPUT CURRENT

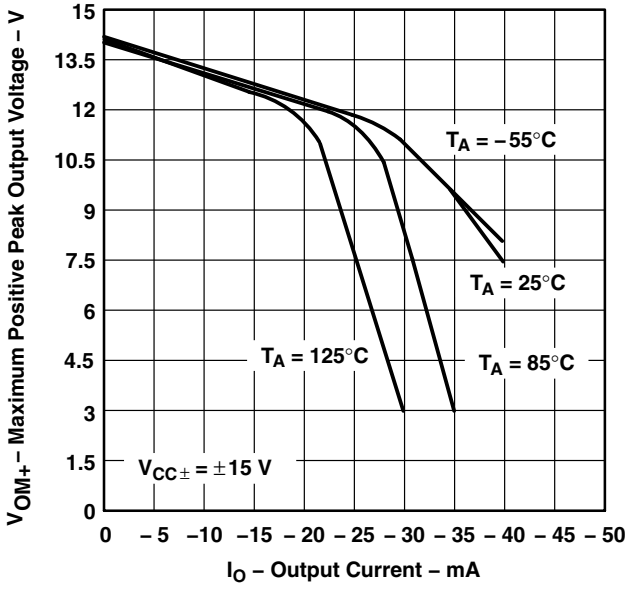


Figure 18

MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE† vs OUTPUT CURRENT

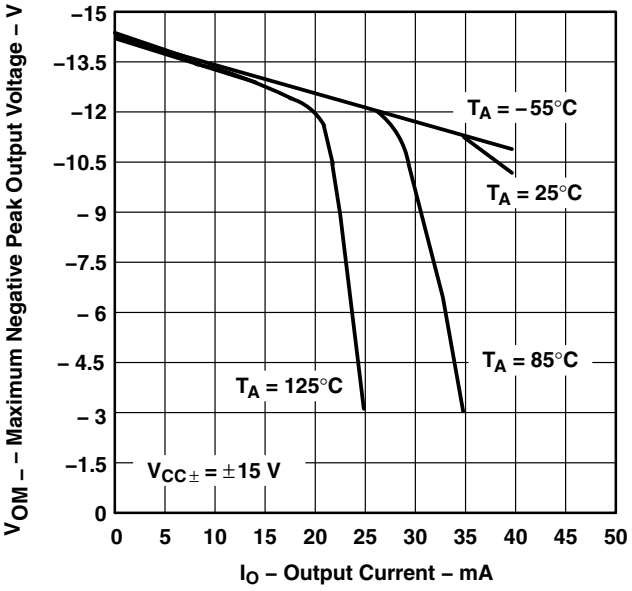


Figure 19

MAXIMUM PEAK OUTPUT VOLTAGE† vs FREE-AIR TEMPERATURE

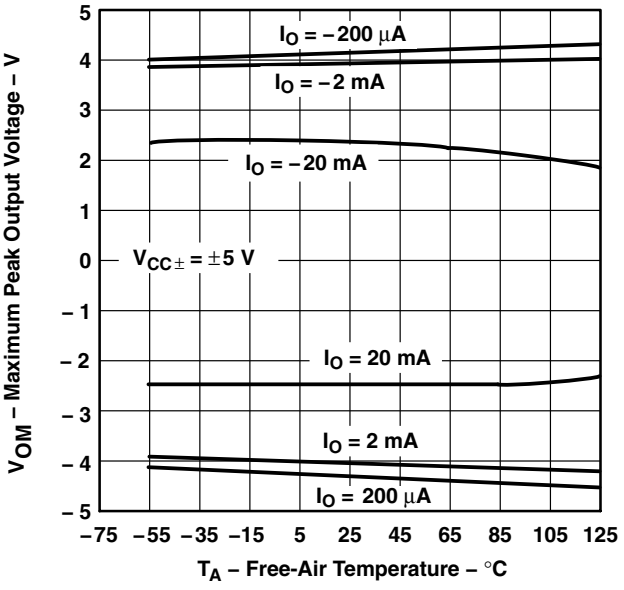


Figure 20

MAXIMUM PEAK OUTPUT VOLTAGE† vs FREE-AIR TEMPERATURE

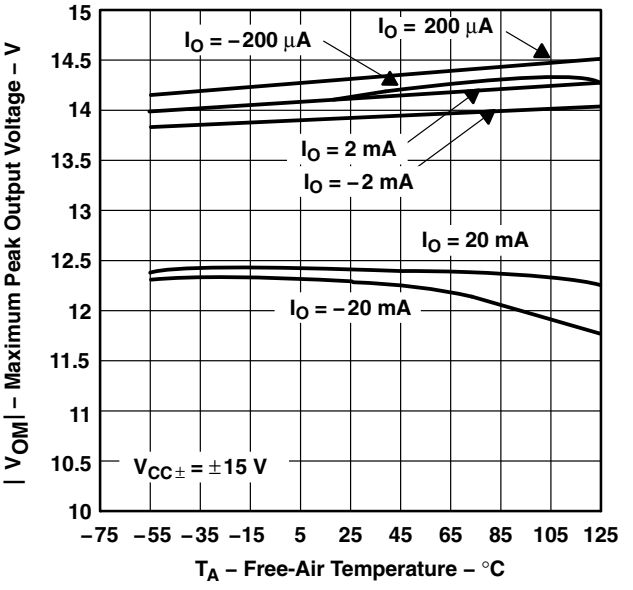


Figure 21

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

MAXIMUM PEAK OUTPUT VOLTAGE vs SUPPLY VOLTAGE

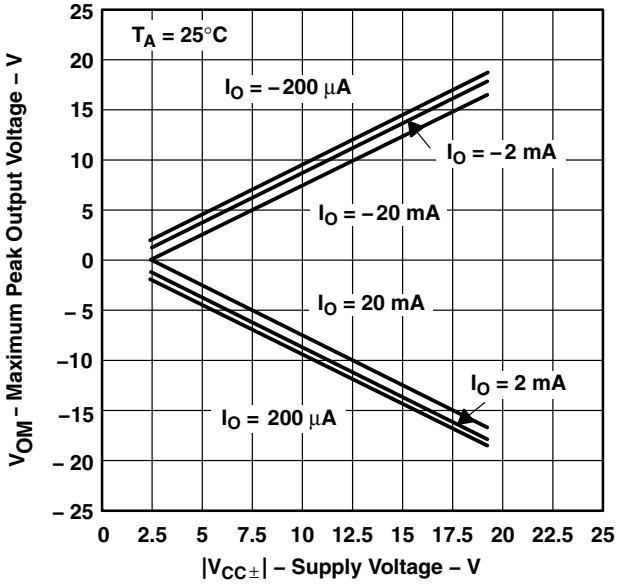


Figure 22

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE† vs FREQUENCY

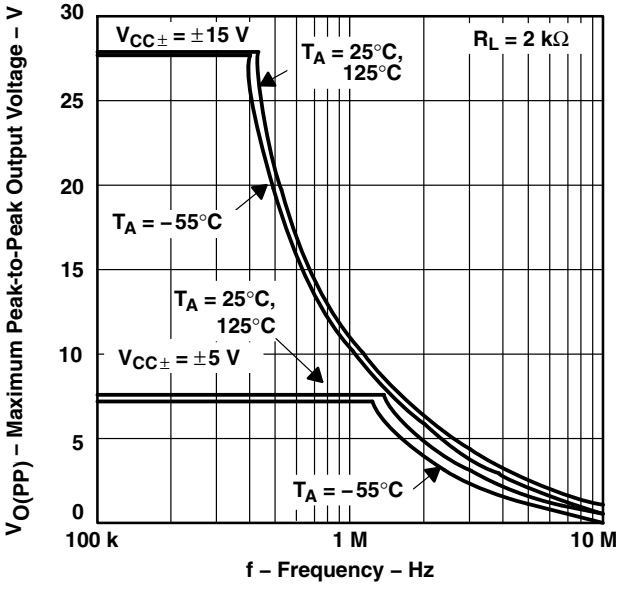


Figure 23

OUTPUT VOLTAGE vs SETTLING TIME

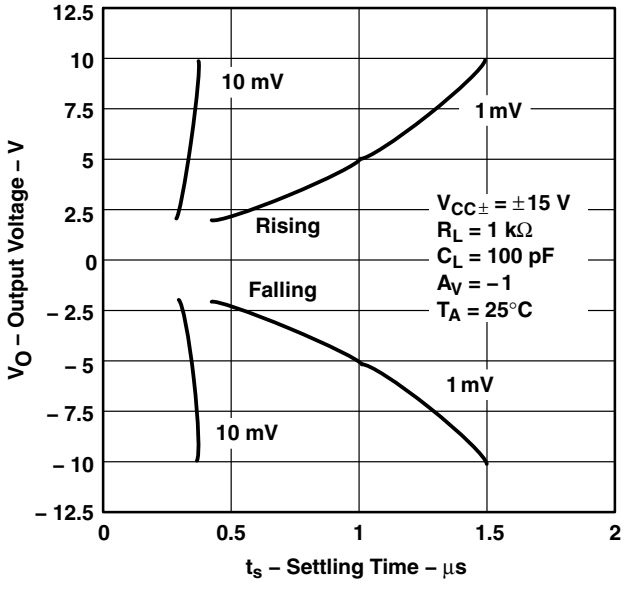


Figure 24

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION vs LOAD RESISTANCE

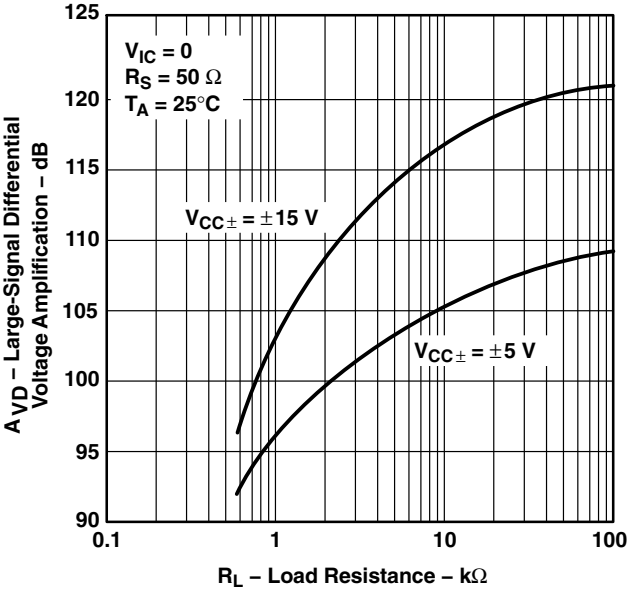


Figure 25

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION† vs FREE-AIR TEMPERATURE

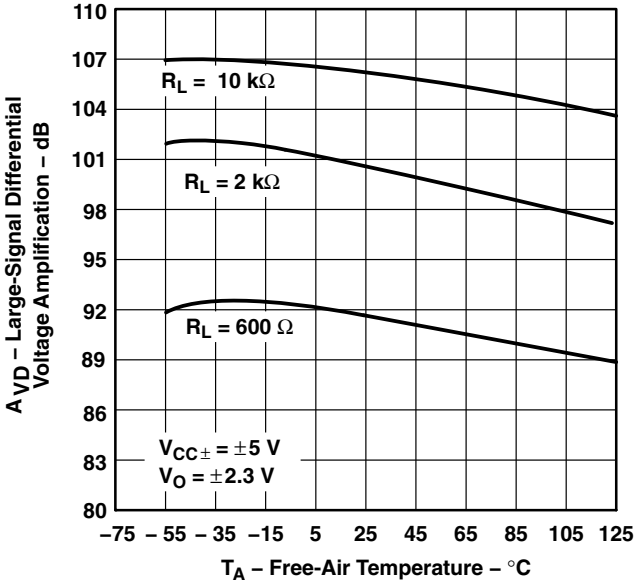


Figure 26

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION† vs FREE-AIR TEMPERATURE

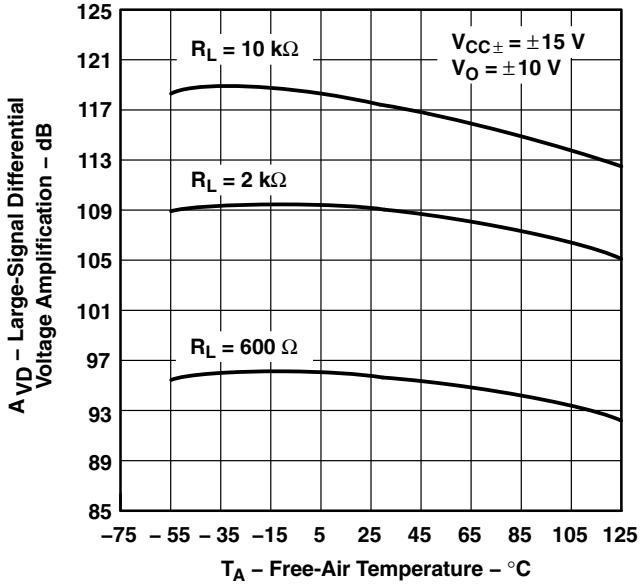


Figure 27

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

SMALL-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT vs FREQUENCY

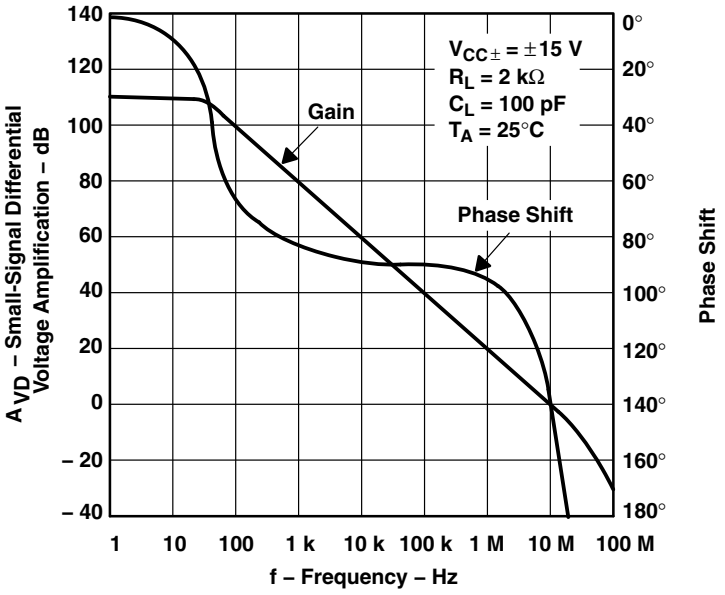


Figure 28

SMALL-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT vs FREQUENCY

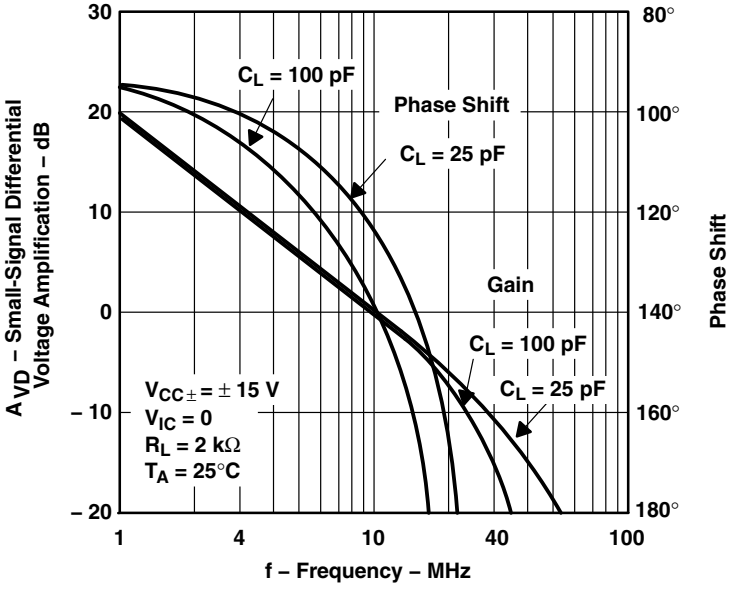


Figure 29

TYPICAL CHARACTERISTICS

COMMON-MODE REJECTION RATIO vs FREQUENCY

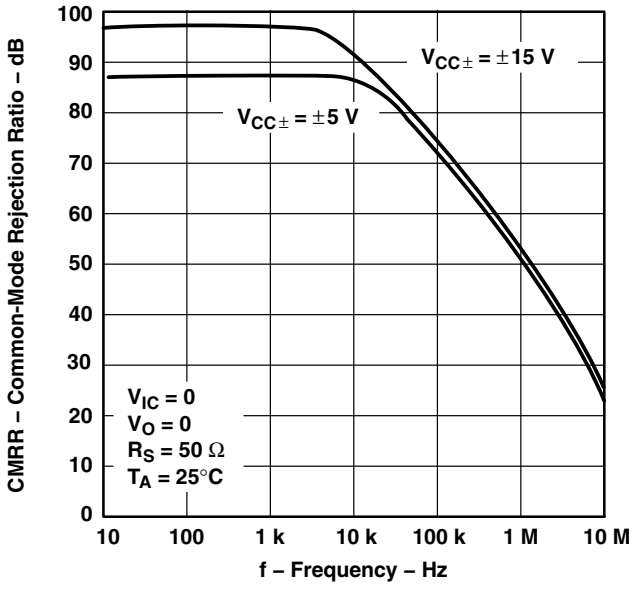


Figure 30

COMMON-MODE REJECTION RATIO† vs FREE-AIR TEMPERATURE

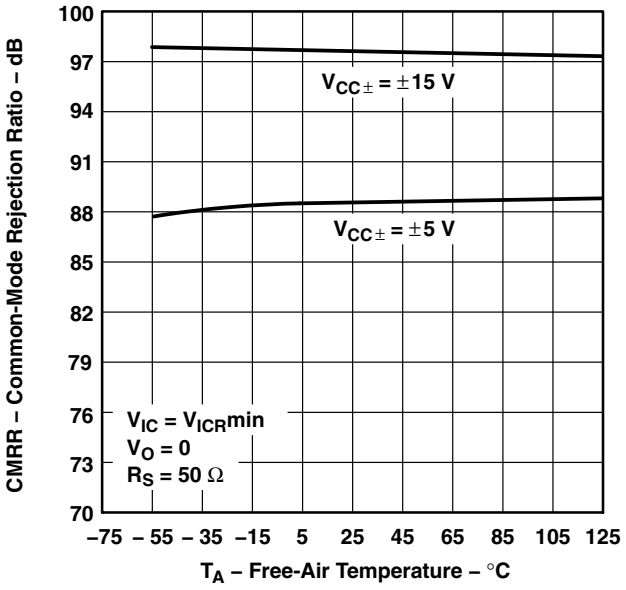


Figure 31

SUPPLY-VOLTAGE REJECTION RATIO vs FREQUENCY

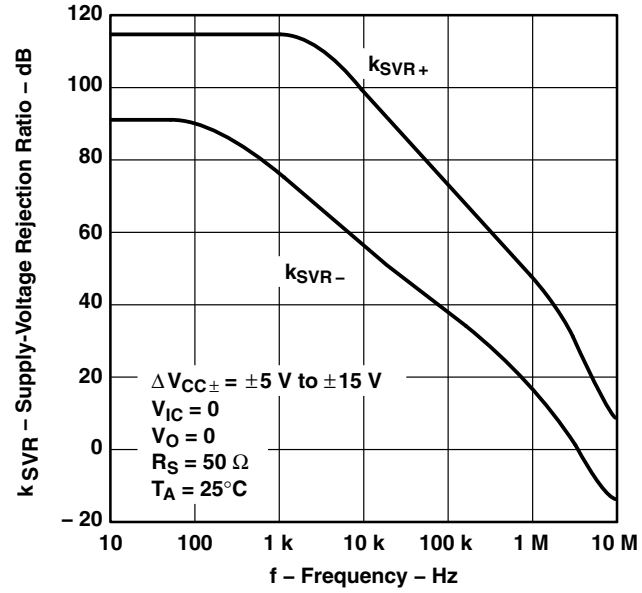


Figure 32

SUPPLY-VOLTAGE REJECTION RATIO† vs FREE-AIR TEMPERATURE

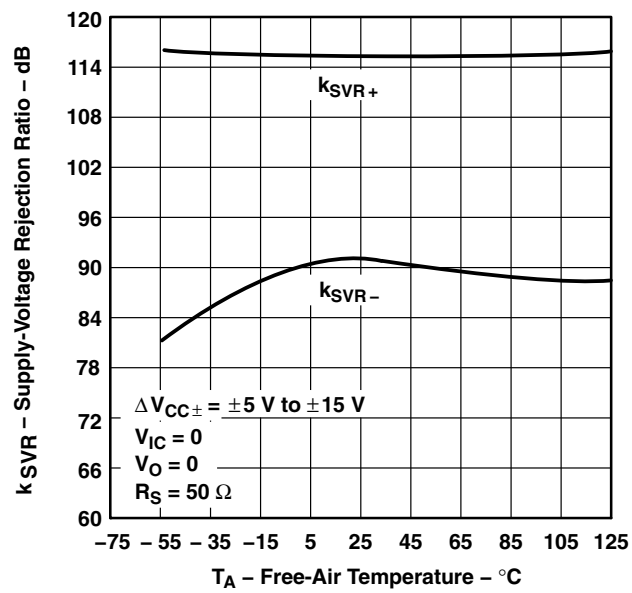


Figure 33

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

TLE2071
SUPPLY CURRENT
vs
SUPPLY VOLTAGE

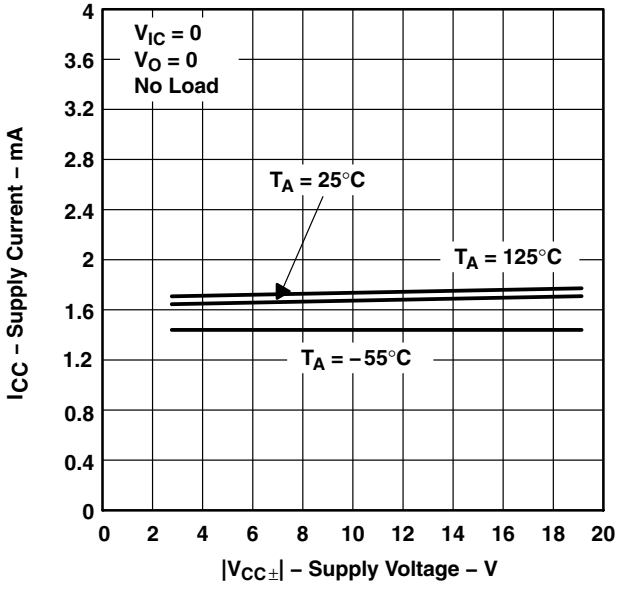


Figure 34

TLE2072
SUPPLY CURRENT
vs
SUPPLY VOLTAGE

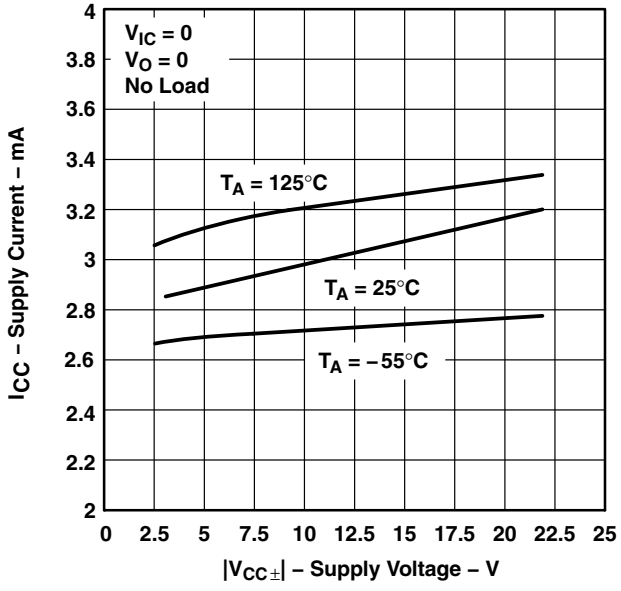


Figure 35

TLE2074
SUPPLY CURRENT
vs
SUPPLY VOLTAGE

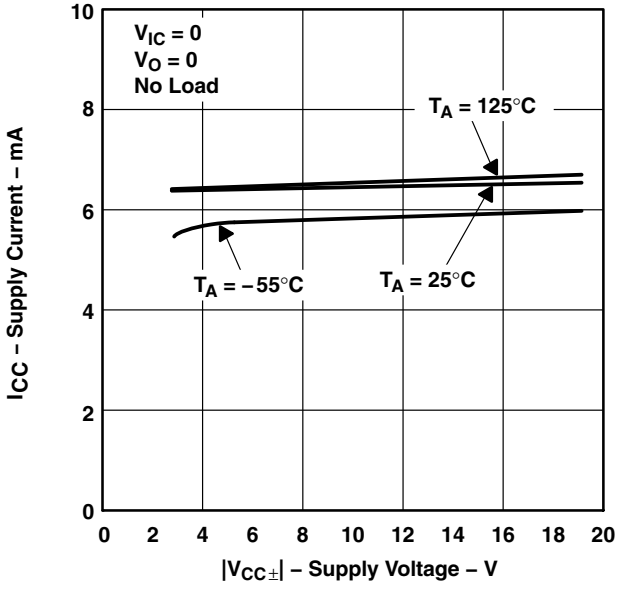


Figure 36

TLE2071
SUPPLY CURRENT†
vs
FREE-AIR TEMPERATURE

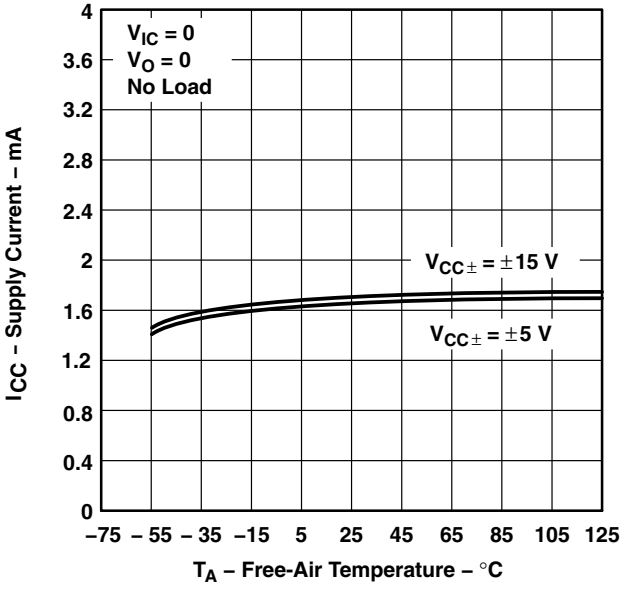


Figure 37

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

TLE2072
SUPPLY CURRENT† vs FREE-AIR TEMPERATURE

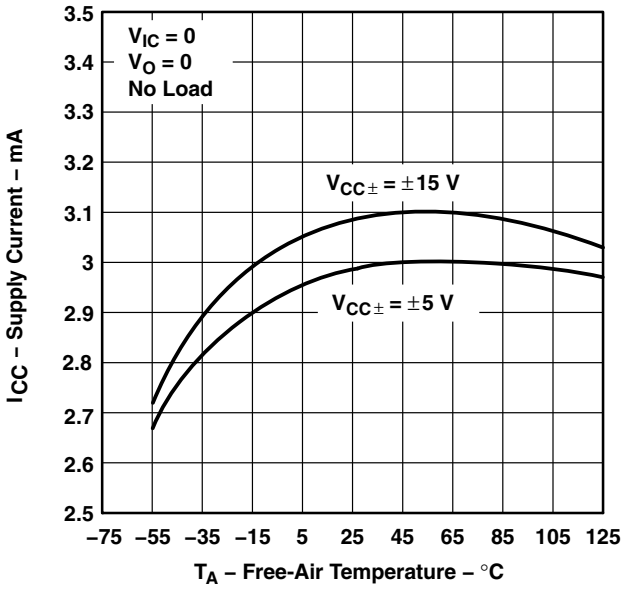


Figure 38

TLE2074
SUPPLY CURRENT† vs FREE-AIR TEMPERATURE

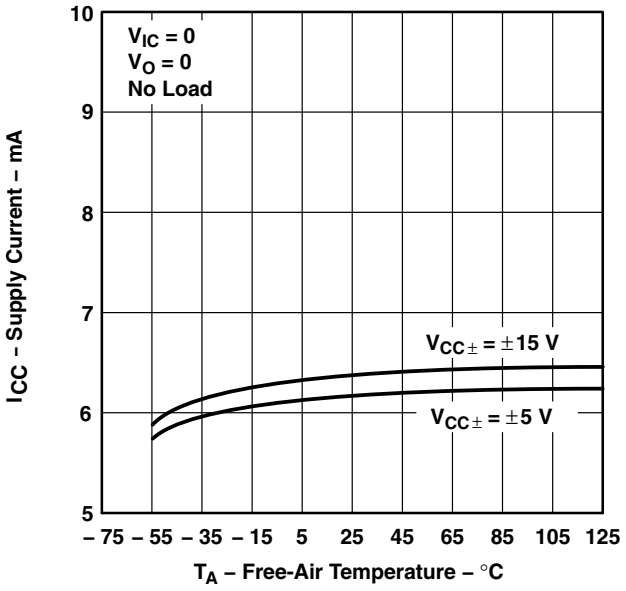


Figure 39

TLE2071
SUPPLY CURRENT vs DIFFERENTIAL INPUT VOLTAGE

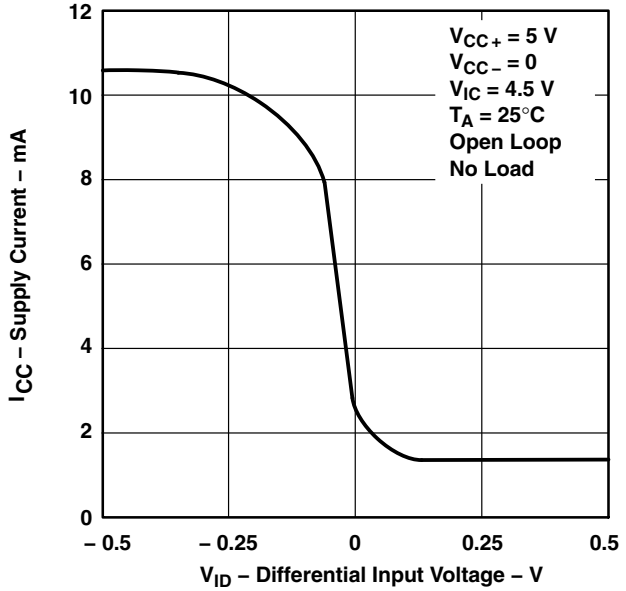


Figure 40

TLE2072
SUPPLY CURRENT vs DIFFERENTIAL INPUT VOLTAGE

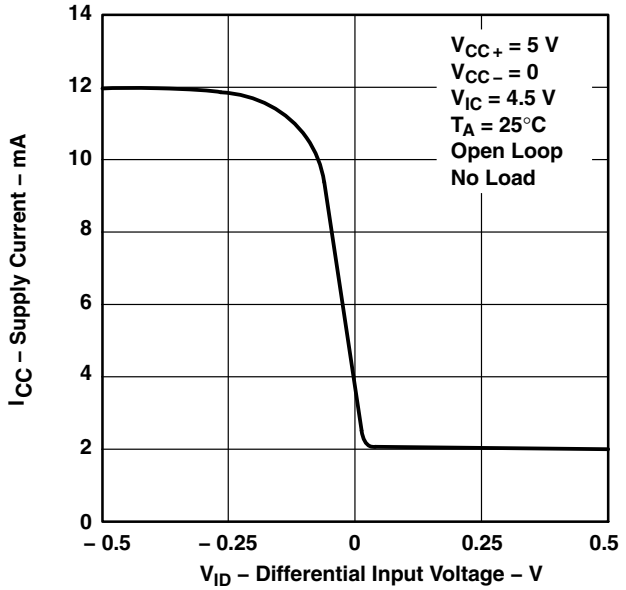


Figure 41

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

**TLE2074
SUPPLY CURRENT
vs
DIFFERENTIAL INPUT VOLTAGE**

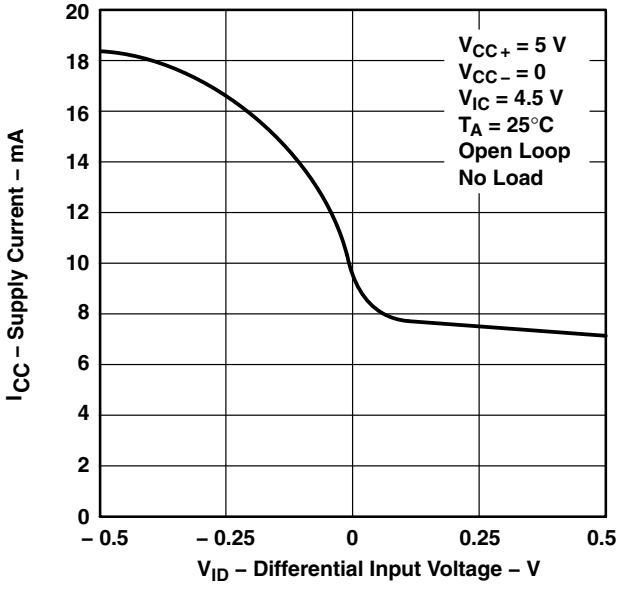


Figure 42

**TLE2071
SUPPLY CURRENT
vs
DIFFERENTIAL INPUT VOLTAGE**

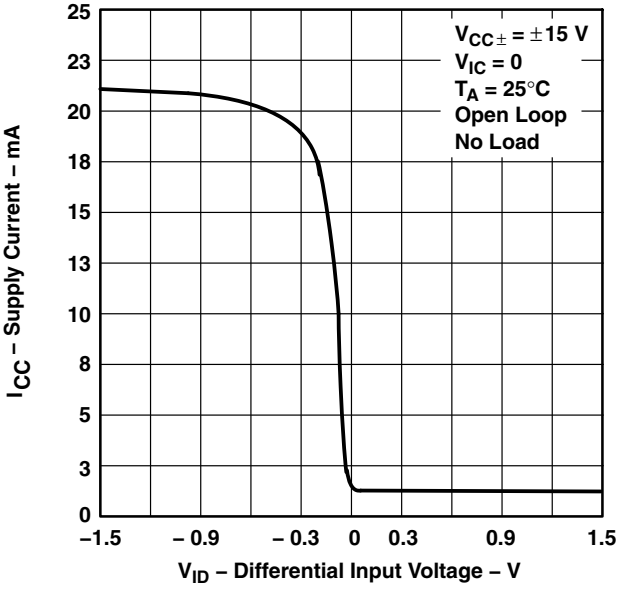


Figure 43

**TLE2072
SUPPLY CURRENT
vs
DIFFERENTIAL INPUT VOLTAGE**

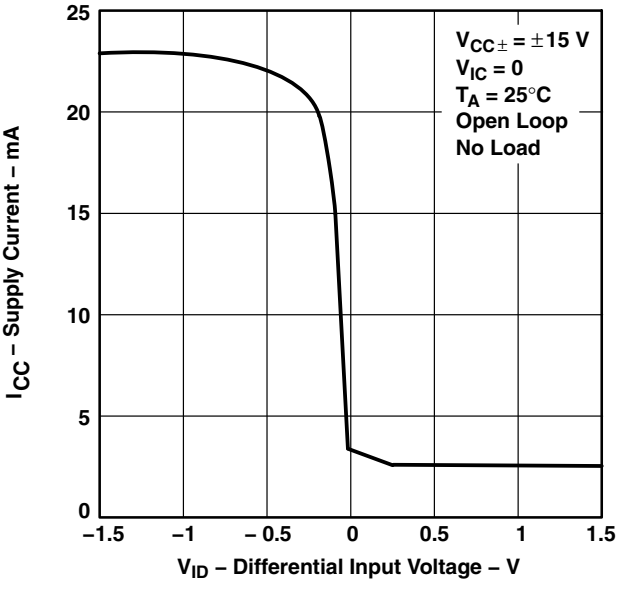


Figure 44

**TLE2074
SUPPLY CURRENT
vs
DIFFERENTIAL INPUT VOLTAGE**

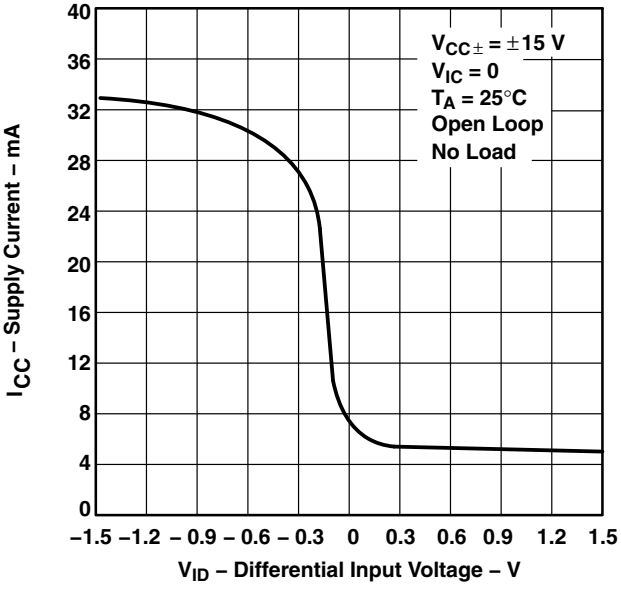


Figure 45

TYPICAL CHARACTERISTICS

SHORT-CIRCUIT OUTPUT CURRENT vs SUPPLY VOLTAGE

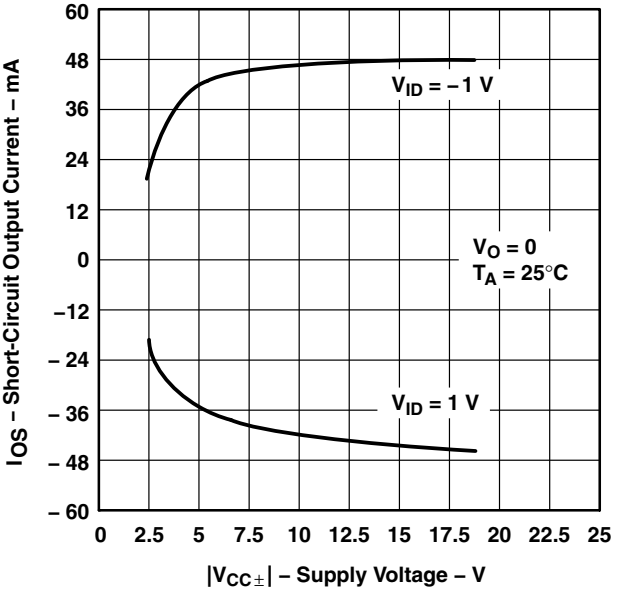


Figure 46

SHORT-CIRCUIT OUTPUT CURRENT vs ELAPSED TIME

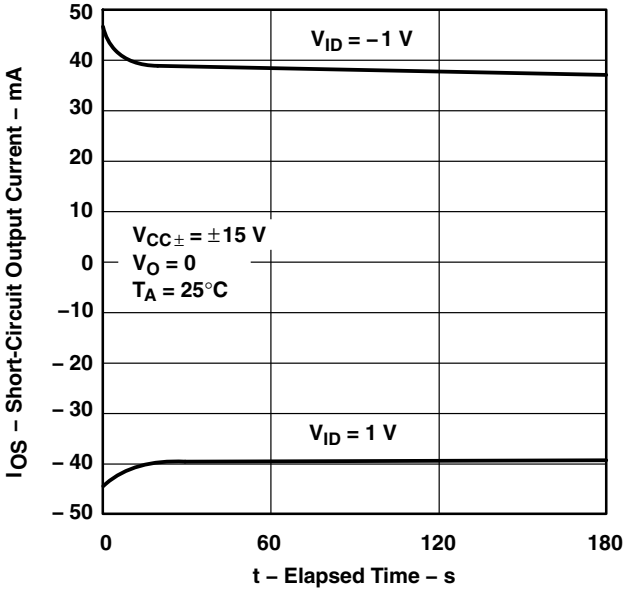


Figure 47

SHORT-CIRCUIT OUTPUT CURRENT† vs FREE-AIR TEMPERATURE

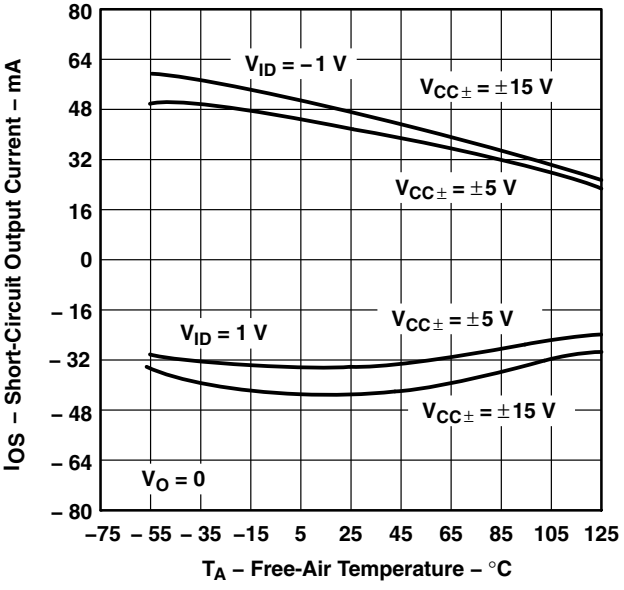


Figure 48

SLEW RATE† vs FREE-AIR TEMPERATURE

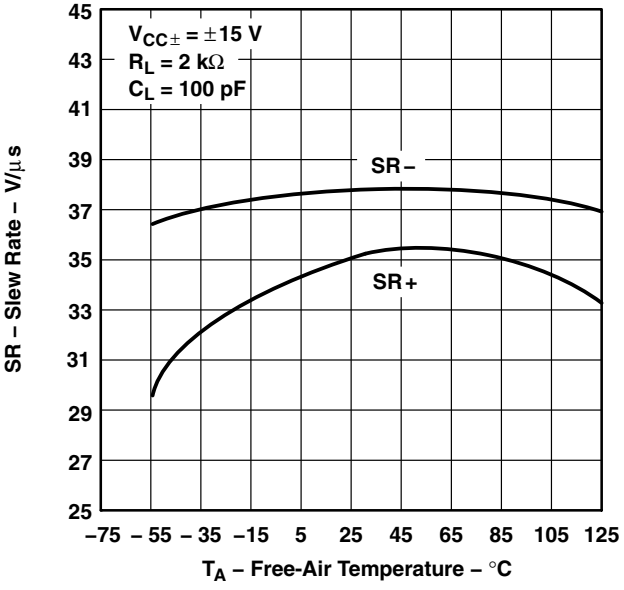


Figure 49

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

SLEW RATE† vs FREE-AIR TEMPERATURE

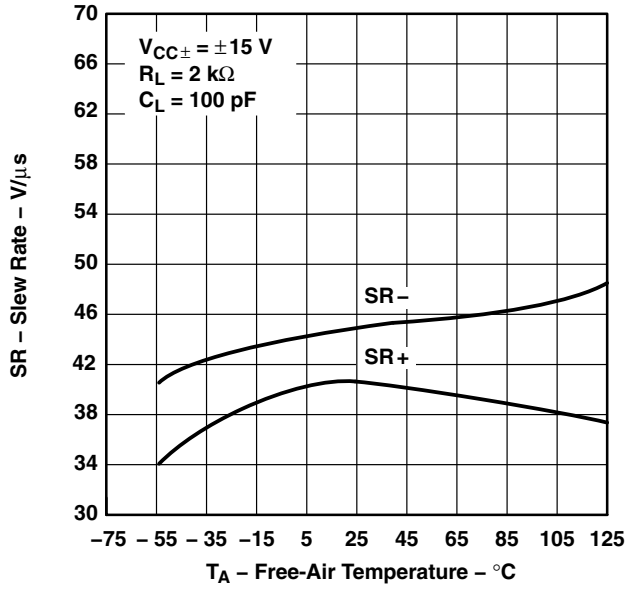


Figure 50

SLEW RATE vs LOAD RESISTANCE

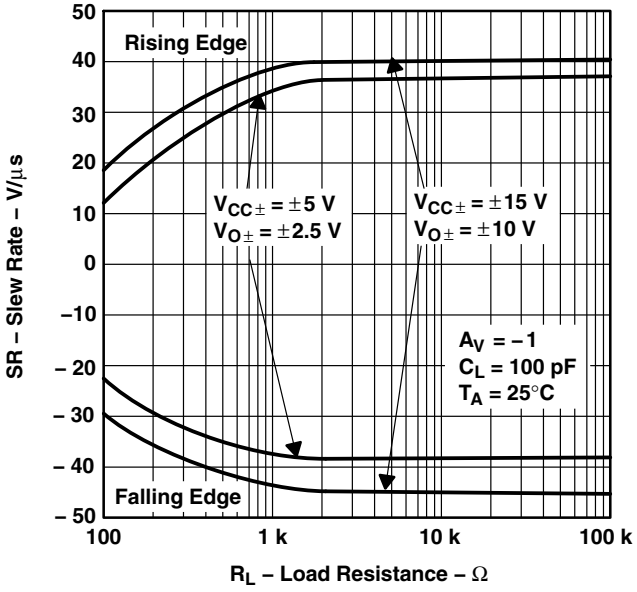


Figure 51

SLEW RATE vs DIFFERENTIAL INPUT VOLTAGE

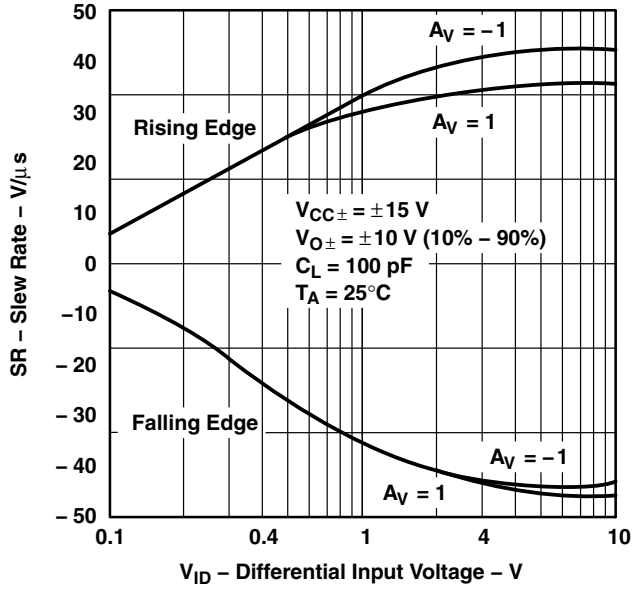


Figure 52

EQUIVALENT INPUT NOISE VOLTAGE (SPECTRAL DENSITY) vs FREQUENCY

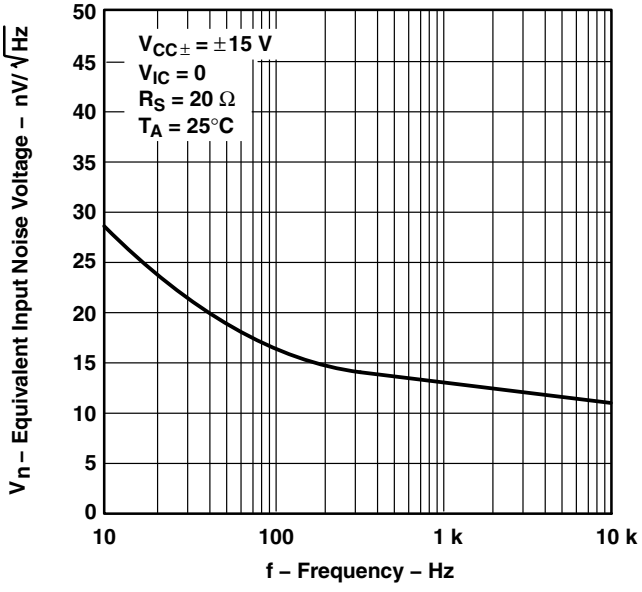


Figure 53

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

INPUT-REFERRED NOISE VOLTAGE vs NOISE BANDWIDTH

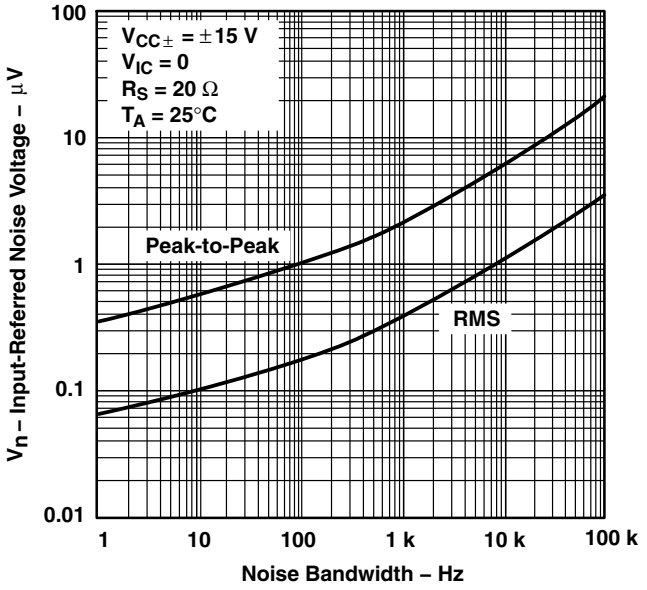


Figure 54

INPUT-REFERRED NOISE VOLTAGE OVER A 10-SECOND TIME INTERVAL

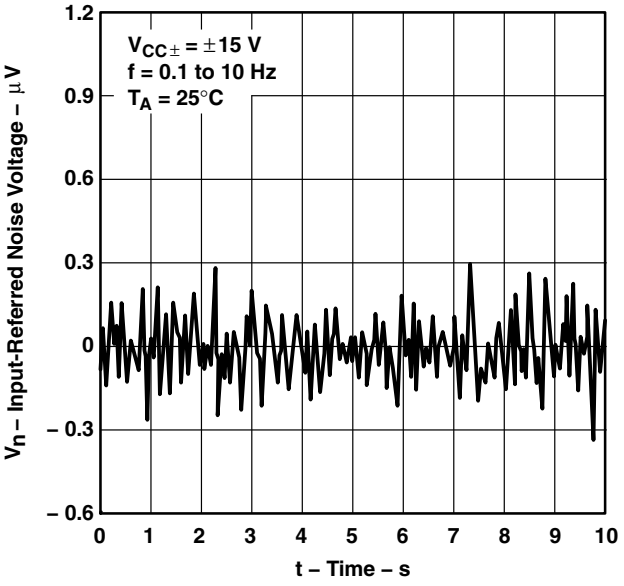


Figure 55

THIRD-OCTAVE SPECTRAL NOISE DENSITY vs FREQUENCY BANDS

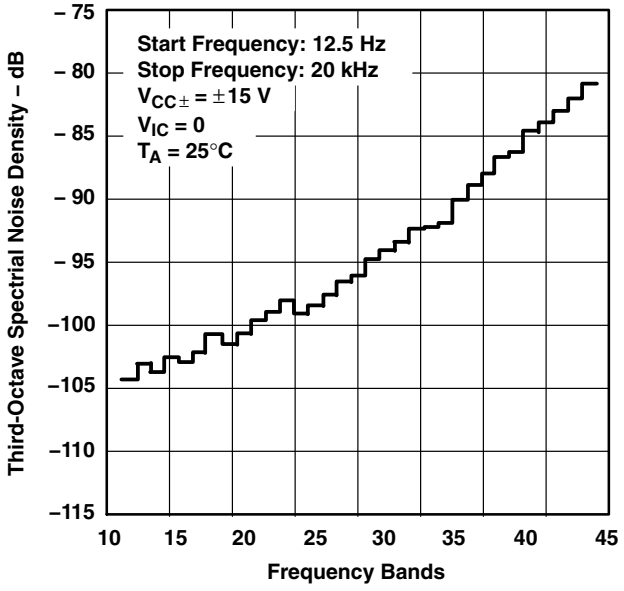


Figure 56

TOTAL HARMONIC DISTORTION PLUS NOISE vs FREQUENCY

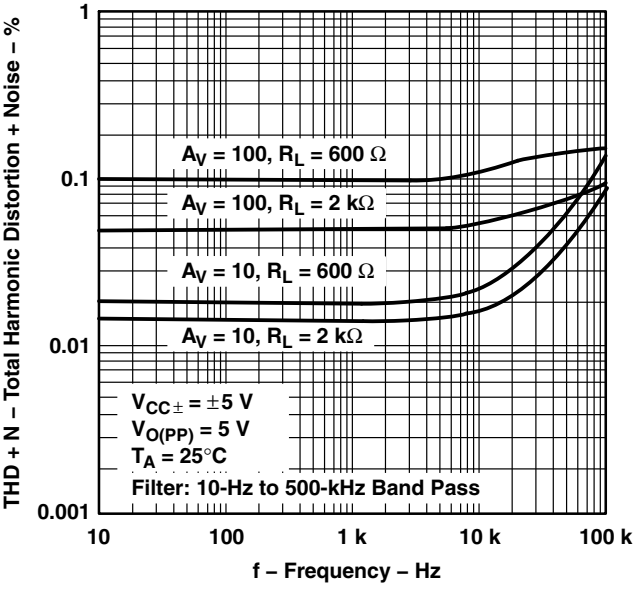


Figure 57

TYPICAL CHARACTERISTICS

TOTAL HARMONIC DISTORTION PLUS NOISE vs FREQUENCY

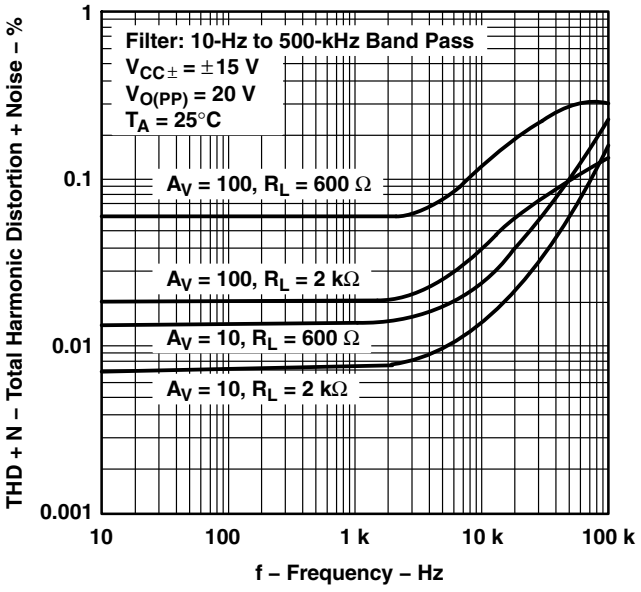


Figure 58

UNITY-GAIN BANDWIDTH vs LOAD CAPACITANCE

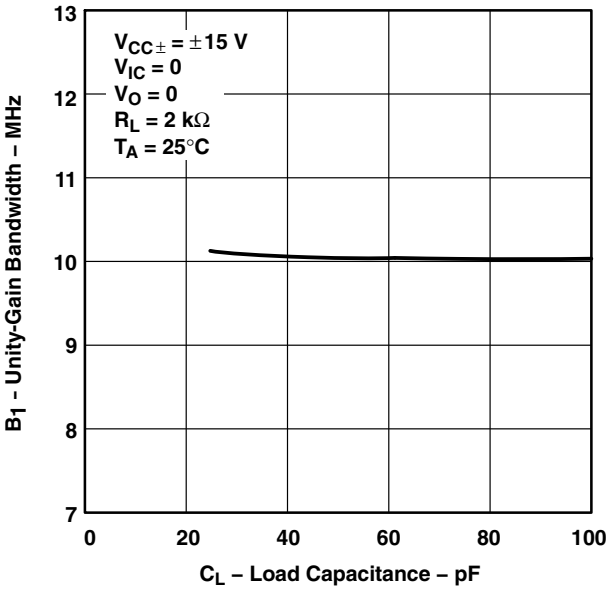


Figure 59

GAIN-BANDWIDTH PRODUCT† vs FREE-AIR TEMPERATURE

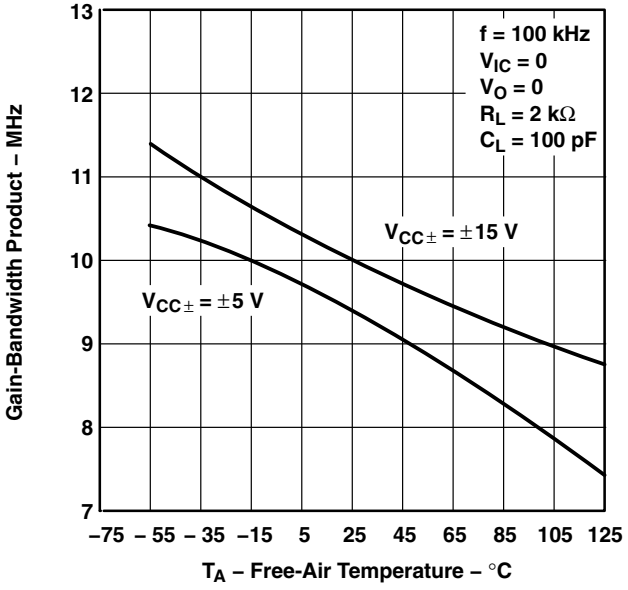


Figure 60

GAIN-BANDWIDTH PRODUCT vs SUPPLY VOLTAGE

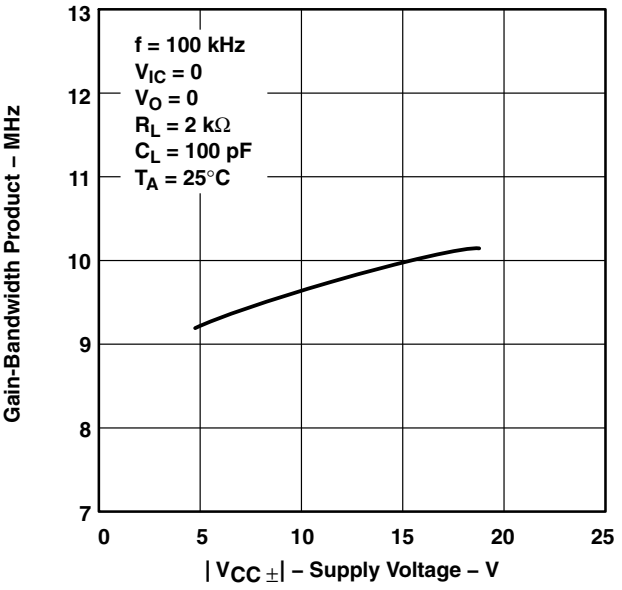


Figure 61

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

GAIN MARGIN vs LOAD CAPACITANCE

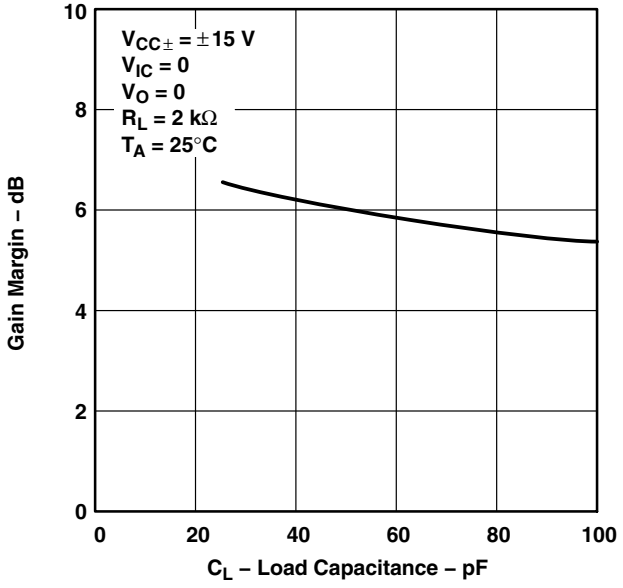


Figure 62

PHASE MARGIN† vs FREE-AIR TEMPERATURE

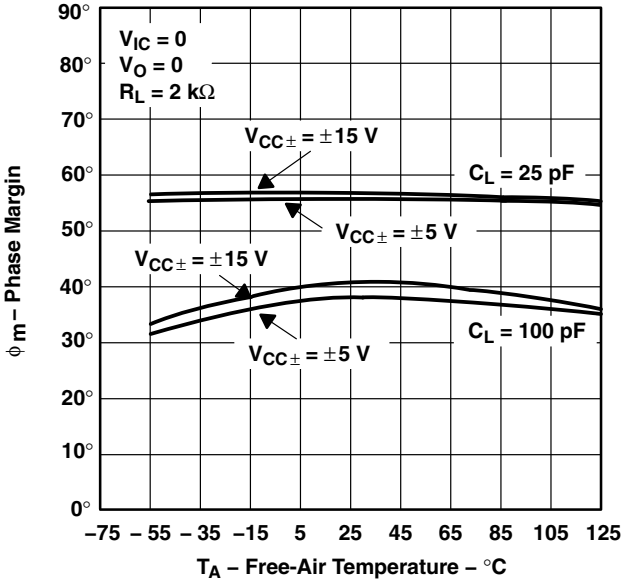


Figure 63

PHASE MARGIN vs SUPPLY VOLTAGE

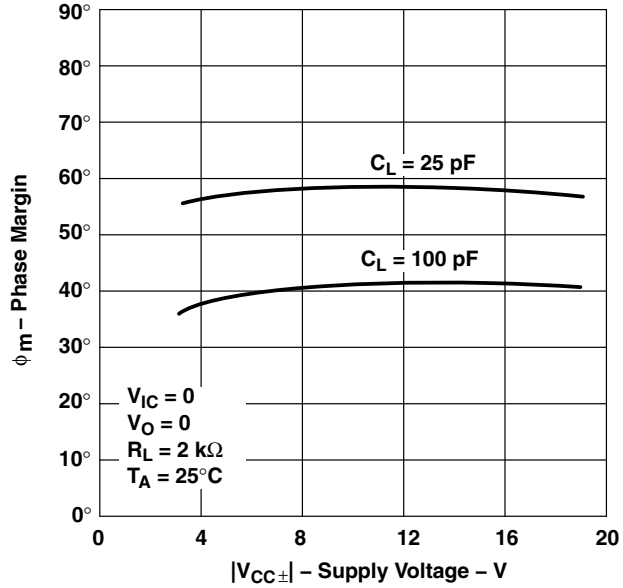


Figure 64

PHASE MARGIN vs LOAD CAPACITANCE

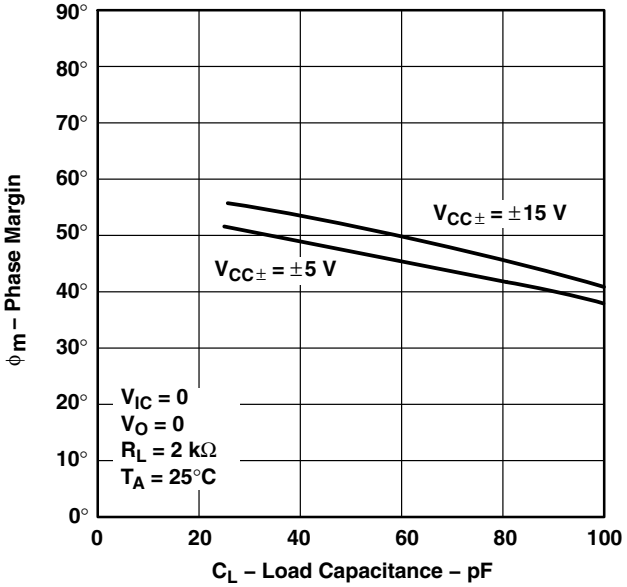


Figure 65

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

NONINVERTING LARGE-SIGNAL PULSE RESPONSE†

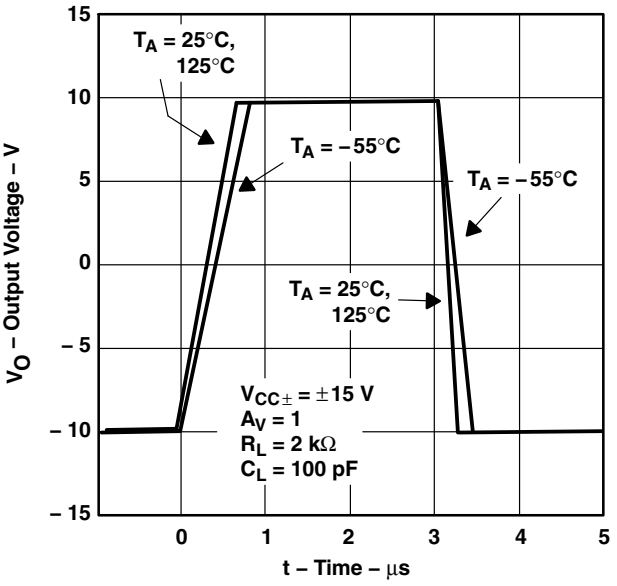


Figure 66

SMALL-SIGNAL PULSE RESPONSE

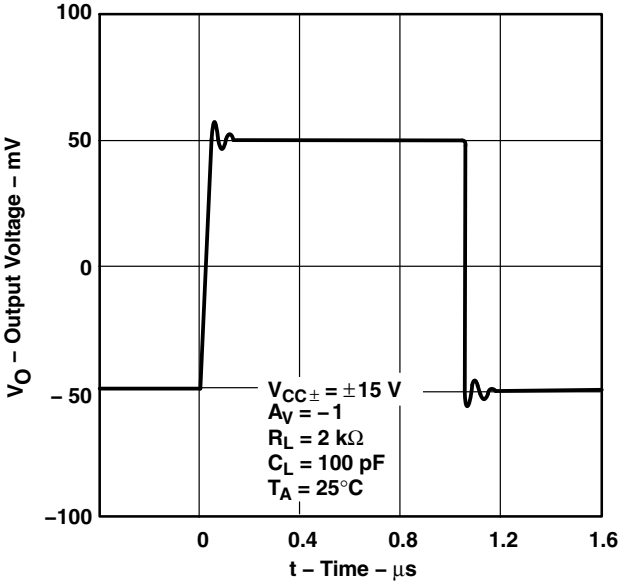


Figure 67

CLOSED-LOOP OUTPUT IMPEDANCE vs FREQUENCY

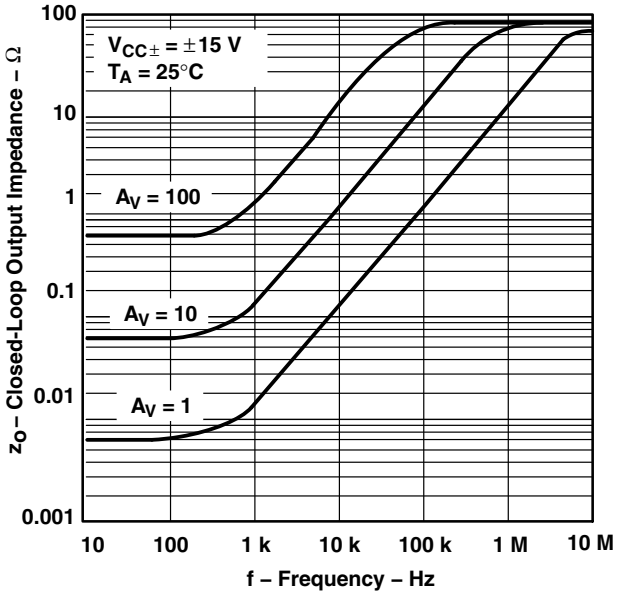


Figure 68

TLE2072 AND TLE2074 CROSSTALK ATTENUATION vs FREQUENCY

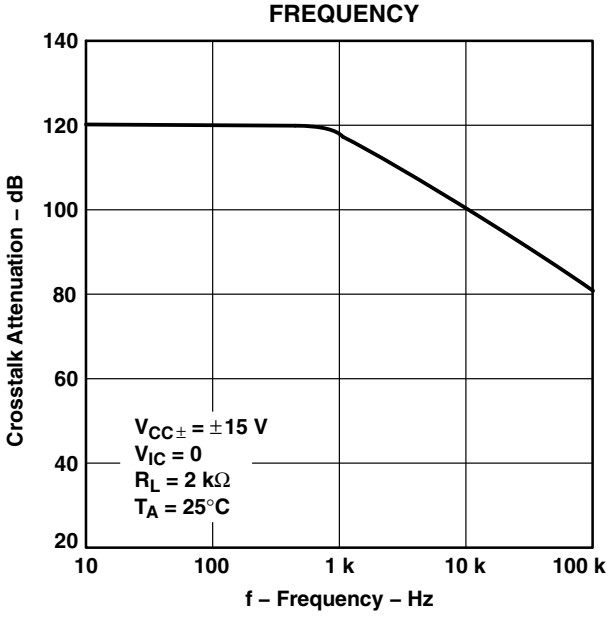


Figure 69

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

APPLICATION INFORMATION

input characteristics

The TLE207x, TLE207xA, and TLE207xB are specified with a minimum and a maximum input voltage that if exceeded at either input could cause the device to malfunction. Because of the extremely high input impedance and resulting low bias current requirements, the TLE207x, TLE207xA, and TLE207xB are well suited for low-level signal processing; however, leakage currents on printed-circuit boards and sockets can easily exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 70). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.

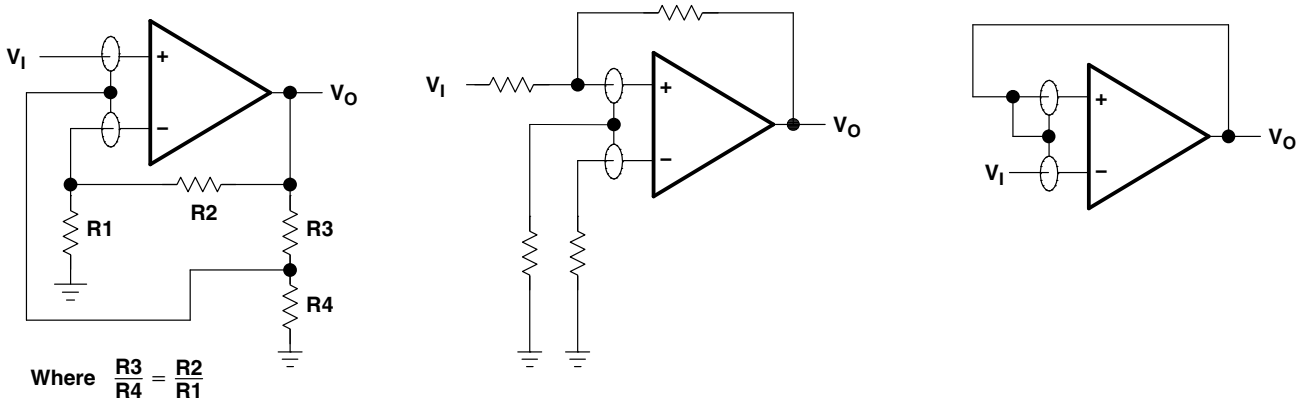


Figure 70. Use of Guard Rings

TLE2071 input offset voltage nulling

The TLE2071 series offers external null pins that can be used to further reduce the input offset voltage. The circuit of Figure 71 can be connected as shown if the feature is desired. When external nulling is not needed, the null pins may be left unconnected.

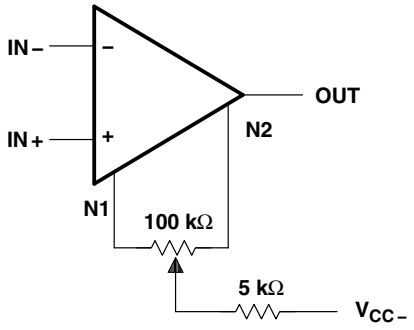


Figure 71. Input Offset Voltage Nulling

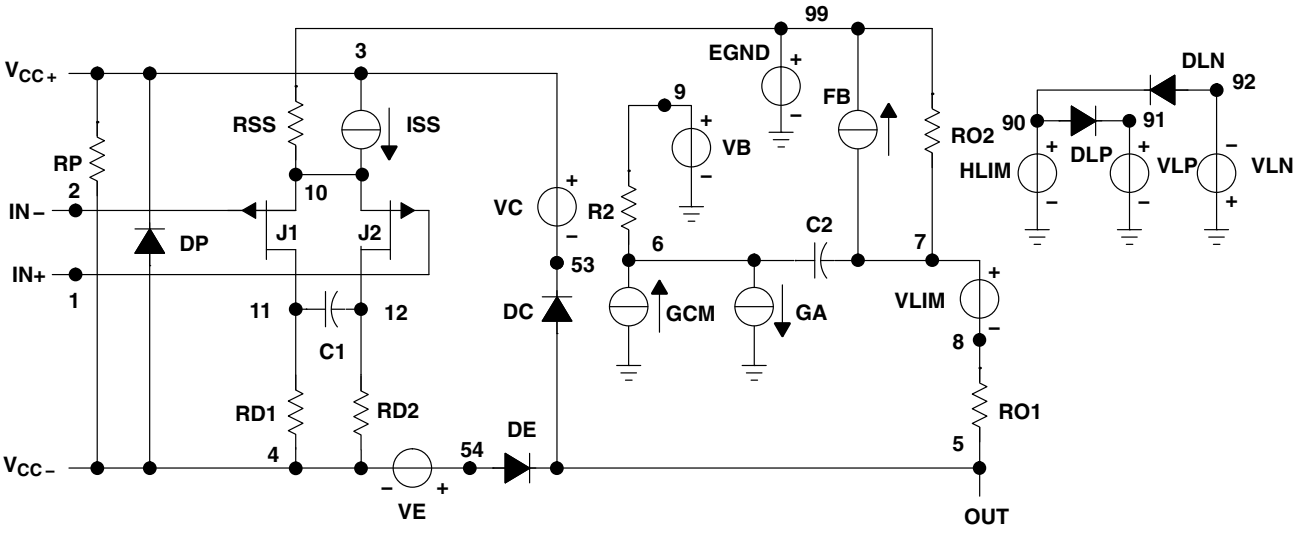
APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using *PSpice*™ *Parts*™ model generation software. The Boyle macromodel (see Note 4) and subcircuit Figure 72 were generated using the TLE207x typical electrical and operating characteristics at $T_A = 25°C$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 4: G.R. Boyle, B.M. Cohn, D. O. Pederson, and J. E. Solomon, “Macromodeling of Integrated Circuit Operational Amplifiers”, *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).




```
.SUBCKT TLE2074 1 2 3 4 5
C1      11      12      2.2E–12
C2      6       7       10.00E–12
DC      5       53      DX
DE      54      5       DX
DLP     90      91      DX
DLN     92      90      DX
DP      4       3       DX
EGND    99      0       POLY (2) (3,0) (4,0) 0 .5 .5
FB      7       99      POLY (5) VB VC VE VLP VLN 0
+ 5.607E6 –6E6 6E6 6E6 –6E6
GA      6       0       11 12 333.0E–6
GCM     0       6       10 99 7.43E–9
ISS     3       10      DC 400.0E–6
HLIM    90      0       VLIM 1K
J1      11      2       10 JX
J2      12      1       10 JX
R2      6       9       100.0E3
RD1     4       11      3.003E3
RD2     4       12      3.003E3
R01     8       5       80
R02     7       99      80
RP      3       4       27.30E3
RSS     10      99      500.0E3
VB      9       0       DC 0
VC      3       53      DC 2.20
VE      54      4       DC 2.20
VLIM    7       8       DC 0
VLP     91      0       DC 45
VLN     0       92      DC 45
.MODEL DX D (IS=800.0E–18)
.MODEL JX PJF (IS=15.00E–12 BETA=554.5E–6
+ VTO=–.6)
.ENDS
```

Figure 72. Boyle Macromodel and Subcircut

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Revision History

Version	Date	Changes
C	Dec–2009	– For TLE2071M/1AM (VCC ±5V) changed V_n NOM & MAX from 28/55 to 48/85 (f = 10 Hz); 11.6/17 to 12/17 (f = 10 KHz), Pg. 16 – For TLE2071M/1AM (VCC ±15V) changed V_n NOM & MAX from 28/55 to 48/85 (f = 10 Hz); 11.6/17 to 12/17 (f = 10 KHz), Pg. 18 – For TLE2072M/2AM (VCC ±5V) changed V_n NOM & MAX from 28/55 to 48/85 (f = 10 Hz); 11.6/17 to 12/17 (f = 10 KHz), Pg. 29 – For TLE2072M/2AM (VCC ±15V) changed V_n NOM & MAX from 28/55 to 48/85 (f = 10 Hz); 11.6/17 to 12/17 (f = 10 KHz), Pg. 31 – For TLE2074M/4AM (VCC ±5V) changed V_n NOM & MAX from 28/55 to 48/85 (f = 10 Hz); 11.6/17 to 12/17 (f = 10 KHz), Pg. 42 – For TLE2074M/4AM (VCC ±15V) changed V_n NOM & MAX from 28/55 to 48/85 (f = 10 Hz); 11.6/17 to 12/17 (f = 10 KHz), Pg. 44

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9460201Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460201Q2A TLE2071 MFKB	Samples
5962-9460201QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460201QPA TLE2071M	Samples
5962-9460202Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460202Q2A TLE2072 MFKB	Samples
5962-9460202QHA	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460202QHA TLE2072M	Samples
5962-9460202QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460202QPA TLE2072M	Samples
5962-9460203Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460203Q2A TLE2074 MFKB	Samples
5962-9460203QCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460203QCA TLE2074MJB	Samples
5962-9460204Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962 9460204Q2A TLE2071 AMFKB	Samples
5962-9460204QHA	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460204QHA TLE2071AM	Samples
5962-9460204QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460204QPA TLE2071AM	Samples
5962-9460205Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460205Q2A TLE2072 AMFKB	Samples
5962-9460205QHA	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460205QHA TLE2072AM	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9460205QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460205QPA TLE2072AM	Samples
5962-9460206Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460206Q2A TLE2074 AMFKB	Samples
5962-9460206QCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460206QCA TLE2074AMJB	Samples
5962-9460206QDA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460206QDA TLE2074AMWB	Samples
TLE2071ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071AC	Samples
TLE2071ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071AC	Samples
TLE2071ACDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071AC	Samples
TLE2071ACP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2071AC	Samples
TLE2071ACPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2071AC	Samples
TLE2071AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071AI	Samples
TLE2071AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071AI	Samples
TLE2071AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071AI	Samples
TLE2071AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071AI	Samples
TLE2071AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2071AI	Samples
TLE2071AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962 9460204Q2A TLE2071 AMFKB	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2071AMJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2071 AMJG	Samples
TLE2071AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460204QPA TLE2071AM	Samples
TLE2071AMUB	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460204QHA TLE2071AM	Samples
TLE2071CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071C	Samples
TLE2071CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071C	Samples
TLE2071CDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI			
TLE2071CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2071CP	Samples
TLE2071CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2071CP	Samples
TLE2071ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071I	Samples
TLE2071IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071I	Samples
TLE2071IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071I	Samples
TLE2071IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2071I	Samples
TLE2071IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2071IP	Samples
TLE2071MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460201Q2A TLE2071 MFKB	Samples
TLE2071MJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2071MJG	Samples
TLE2071MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460201QPA TLE2071M	Samples
TLE2072ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072AC	Samples
TLE2072ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072AC	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2072ACP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2072AC	Samples
TLE2072ACPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2072AC	Samples
TLE2072AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072AI	Samples
TLE2072AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072AI	Samples
TLE2072AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072AI	Samples
TLE2072AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072AI	Samples
TLE2072AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2072AI	Samples
TLE2072AIPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2072AI	Samples
TLE2072AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460205Q2A TLE2072 AMFKB	Samples
TLE2072AMJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2072 AMJG	Samples
TLE2072AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460205QPA TLE2072AM	Samples
TLE2072AMUB	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460205QHA TLE2072AM	Samples
TLE2072CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072C	Samples
TLE2072CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072C	Samples
TLE2072CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072C	Samples
TLE2072CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072C	Samples
TLE2072CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2072CP	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2072ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072I	Samples
TLE2072IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2072I	Samples
TLE2072IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2072I	Samples
TLE2072IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2072I	Samples
TLE2072IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2072IP	Samples
TLE2072IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2072IP	Samples
TLE2072MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460202Q2A TLE2072 MFKB	Samples
TLE2072MJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2072MJG	Samples
TLE2072MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460202QPA TLE2072M	Samples
TLE2072MUB	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9460202QHA TLE2072M	Samples
TLE2074ACDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074AC	Samples
TLE2074ACDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074AC	Samples
TLE2074ACDWR	OBSOLETE	SOIC	DW	16		TBD	Call TI	Call TI			
TLE2074ACN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074ACN	Samples
TLE2074ACNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074ACN	Samples
TLE2074AIDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074AI	Samples
TLE2074AIDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074AI	Samples
TLE2074AIDWR	OBSOLETE	SOIC	DW	16		TBD	Call TI	Call TI			

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2074AIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074AIN	Samples
TLE2074AINE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074AIN	Samples
TLE2074AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460206Q2A TLE2074 AMFKB	Samples
TLE2074AMJ	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2074AMJ	Samples
TLE2074AMJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460206QC A TLE2074AMJB	Samples
TLE2074AMWB	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460206QD A TLE2074AMWB	Samples
TLE2074CDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074C	Samples
TLE2074CDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074C	Samples
TLE2074CDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074C	Samples
TLE2074CDWRG4	ACTIVE	SOIC	DW	16		TBD	Call TI	Call TI			Samples
TLE2074CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074CN	Samples
TLE2074CNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074CN	Samples
TLE2074IDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074I	Samples
TLE2074IDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074I	Samples
TLE2074IDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2074I	Samples
TLE2074IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074IN	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2074INE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2074IN	Samples
TLE2074MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9460203Q2A TLE2074 MFKB	Samples
TLE2074MJ	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2074MJ	Samples
TLE2074MJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460203QCA TLE2074MJB	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TLE2071, TLE2071A, TLE2071AM, TLE2071M, TLE2072, TLE2072A, TLE2072AM, TLE2072M, TLE2074, TLE2074A, TLE2074AM, TLE2074M :

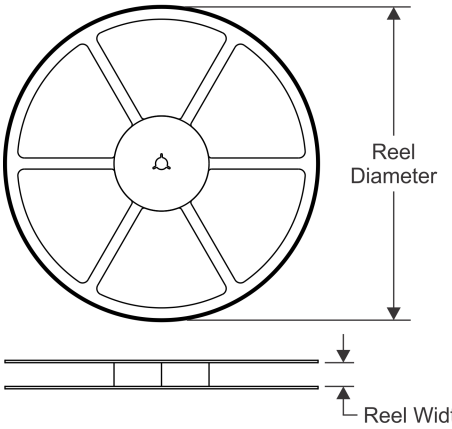
- Catalog: TLE2071A, TLE2071, TLE2072A, TLE2072, TLE2074A, TLE2074
- Automotive: TLE2071-Q1, TLE2071A-Q1, TLE2071A-Q1, TLE2071-Q1, TLE2072A-Q1, TLE2072A-Q1
- Military: TLE2071M, TLE2071AM, TLE2072M, TLE2072AM, TLE2074M, TLE2074AM

NOTE: Qualified Version Definitions:

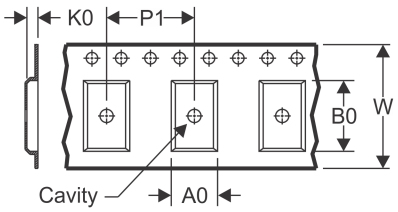
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

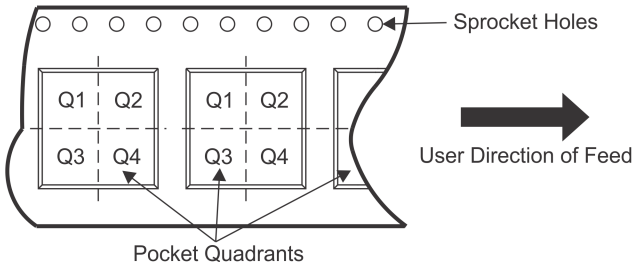


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

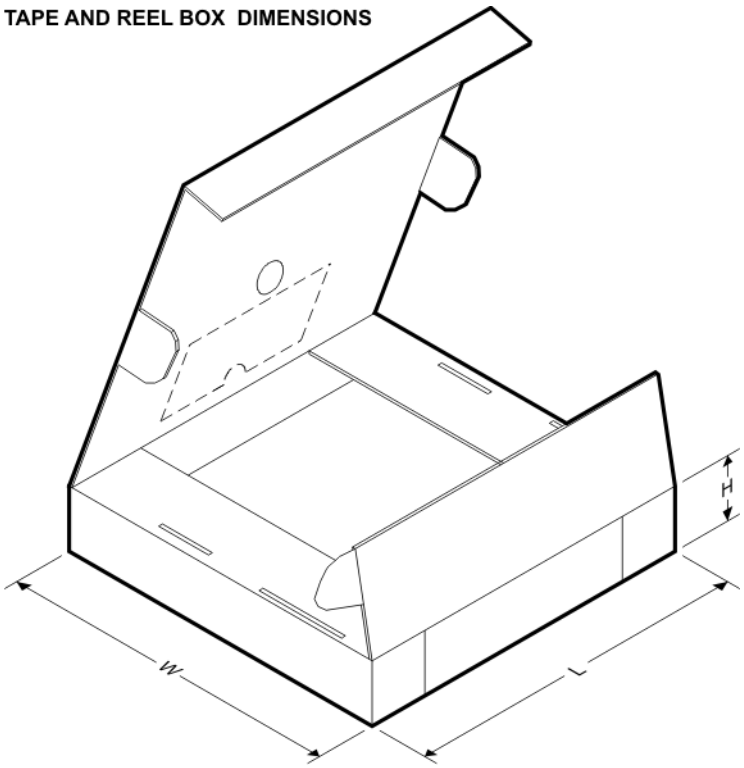
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2071ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2071AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2071IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2072AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2072CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2072IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2072IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2072IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2074CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TLE2074IDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

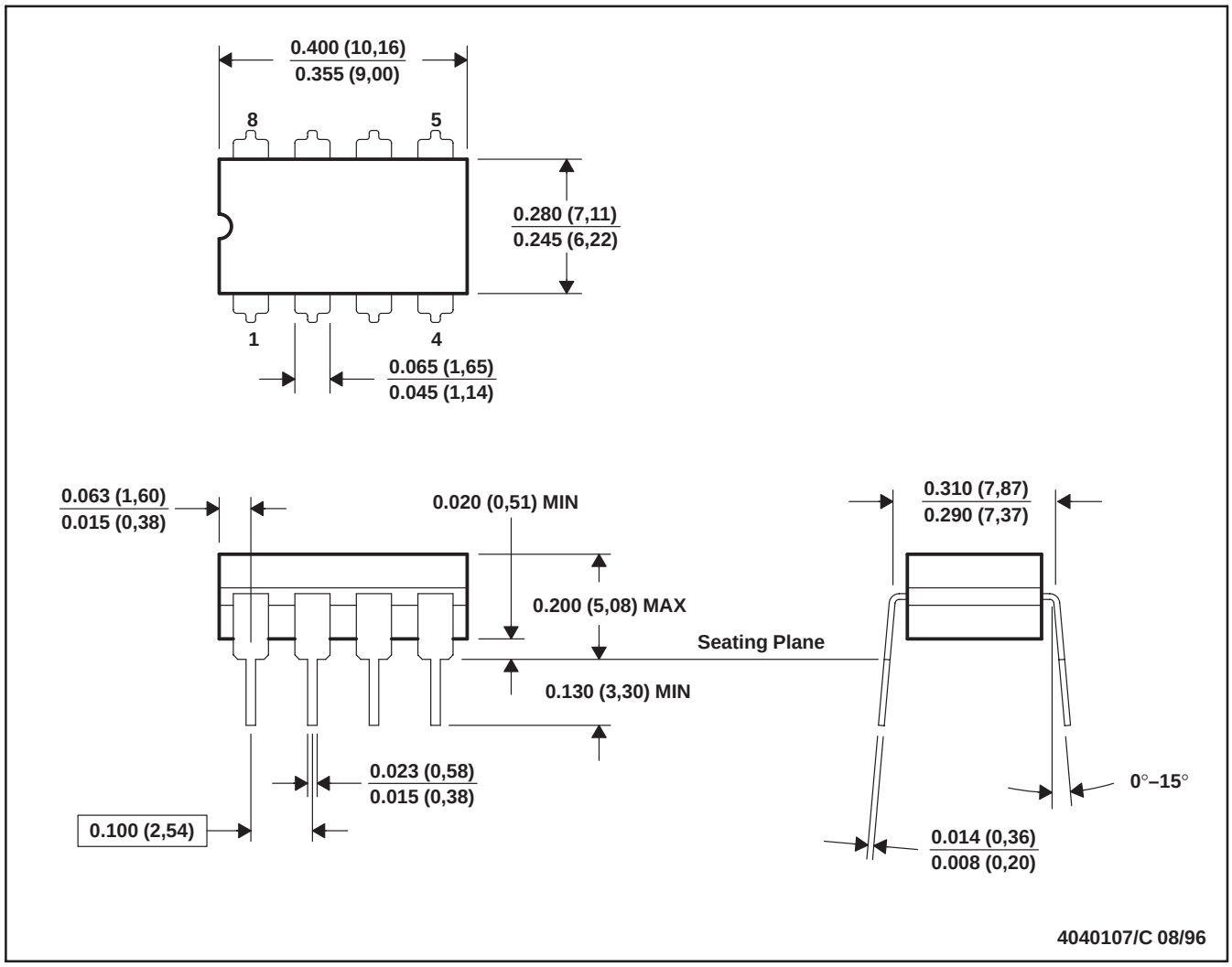


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2071ACDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2071AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2071IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2072AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2072CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2072IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2072IDR	SOIC	D	8	2500	367.0	367.0	38.0
TLE2072IDR	SOIC	D	8	2500	367.0	367.0	35.0
TLE2074CDWR	SOIC	DW	16	2000	367.0	367.0	38.0
TLE2074IDWR	SOIC	DW	16	2000	367.0	367.0	38.0

MCER001A – JANUARY 1995 – REVISED JANUARY 1997

JG (R-GDIP-T8) **CERAMIC DUAL-IN-LINE**

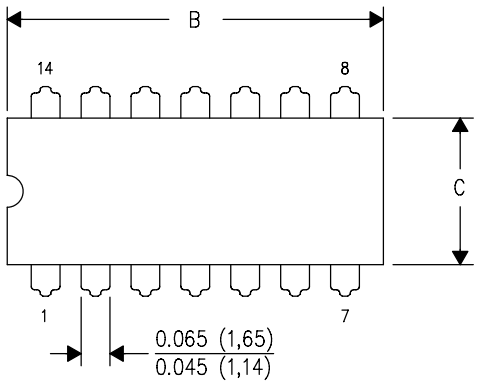


NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification.
E. Falls within MIL STD 1835 GDIP1-T8

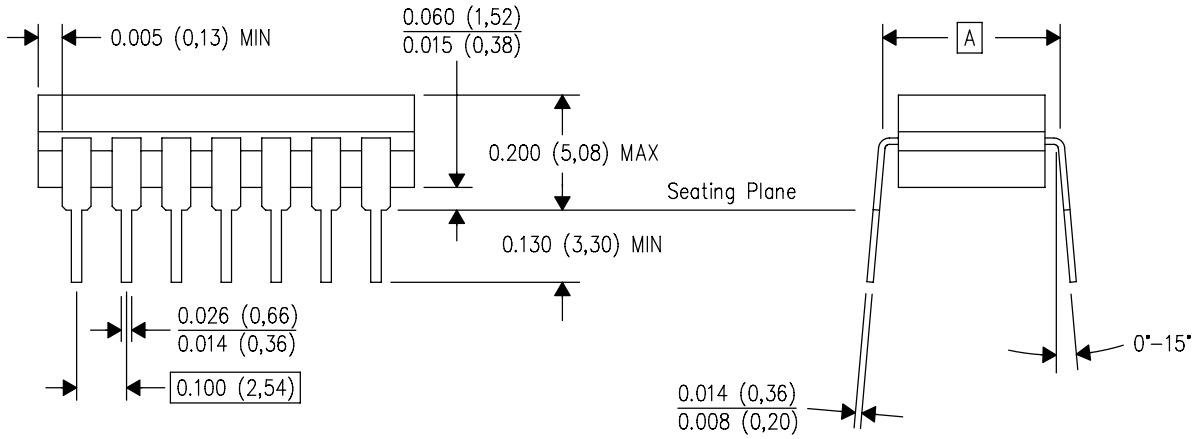
J (R–GDIP–T**)

14 LEADS SHOWN

CERAMIC DUAL IN–LINE PACKAGE



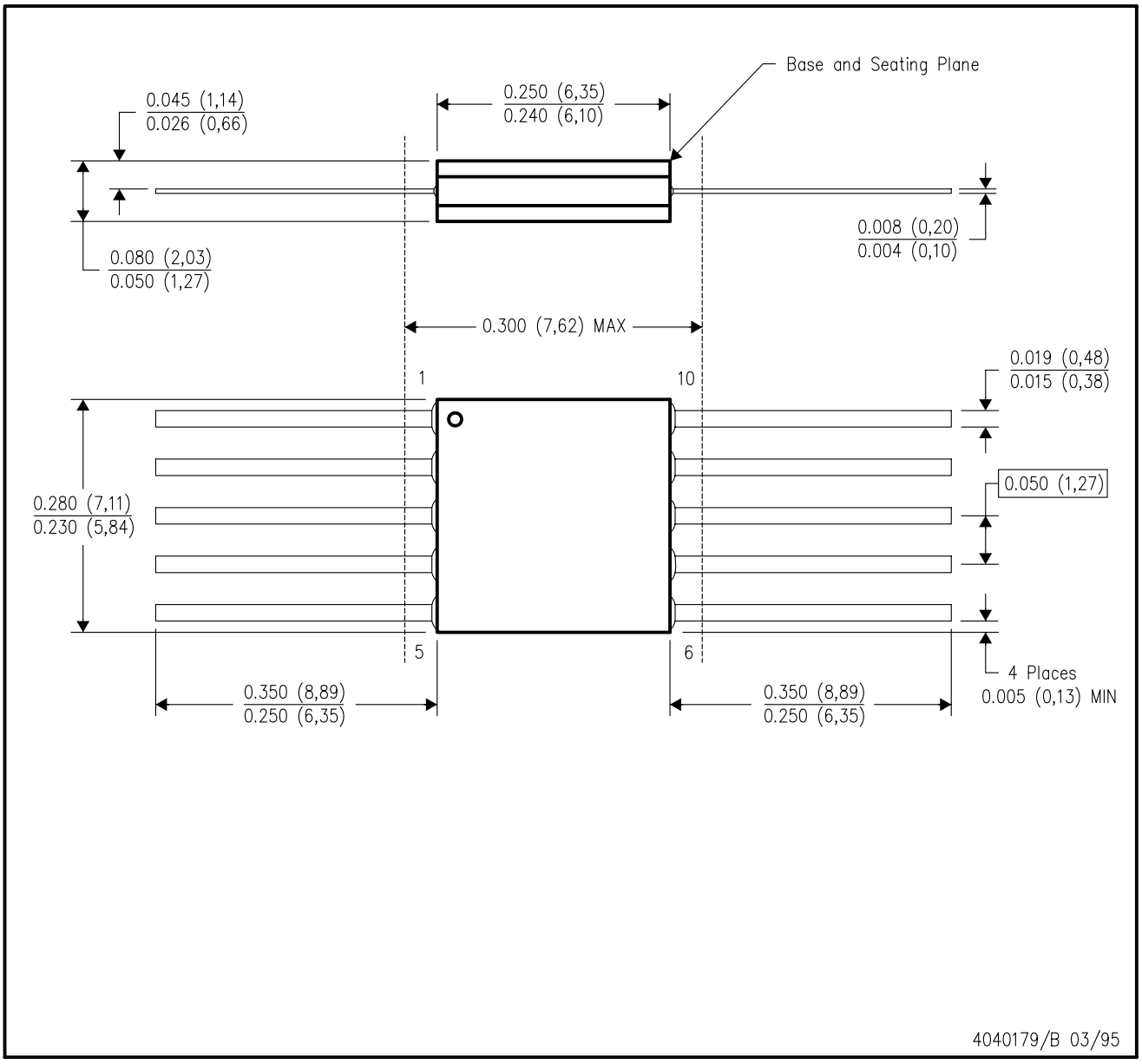
DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

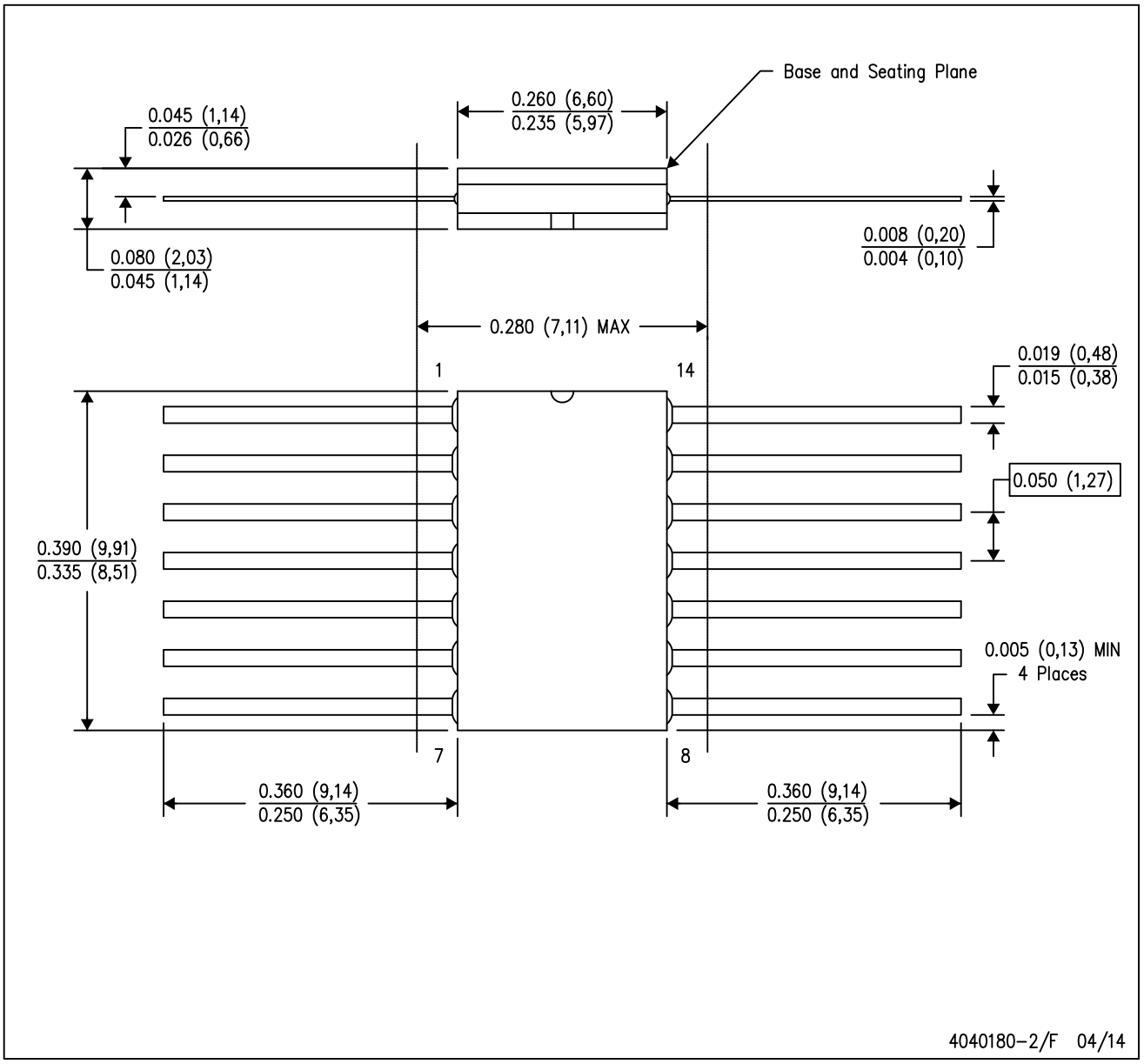
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package is hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1–T14, GDIP1–T16, GDIP1–T18 and GDIP1–T20.

U (S–GDFP–F10) CERAMIC DUAL FLATPACK



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only.
E. Falls within MIL STD 1835 GDFP1–F10 and JEDEC MO–092AA

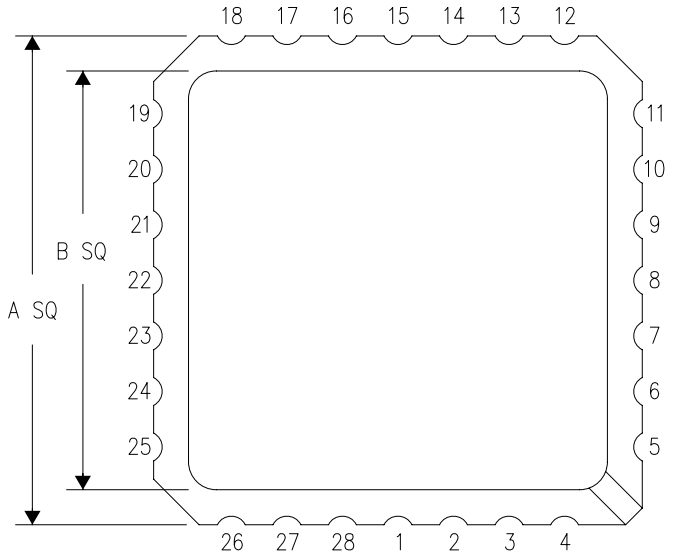
W (R–GDFP–F14) CERAMIC DUAL FLATPACK



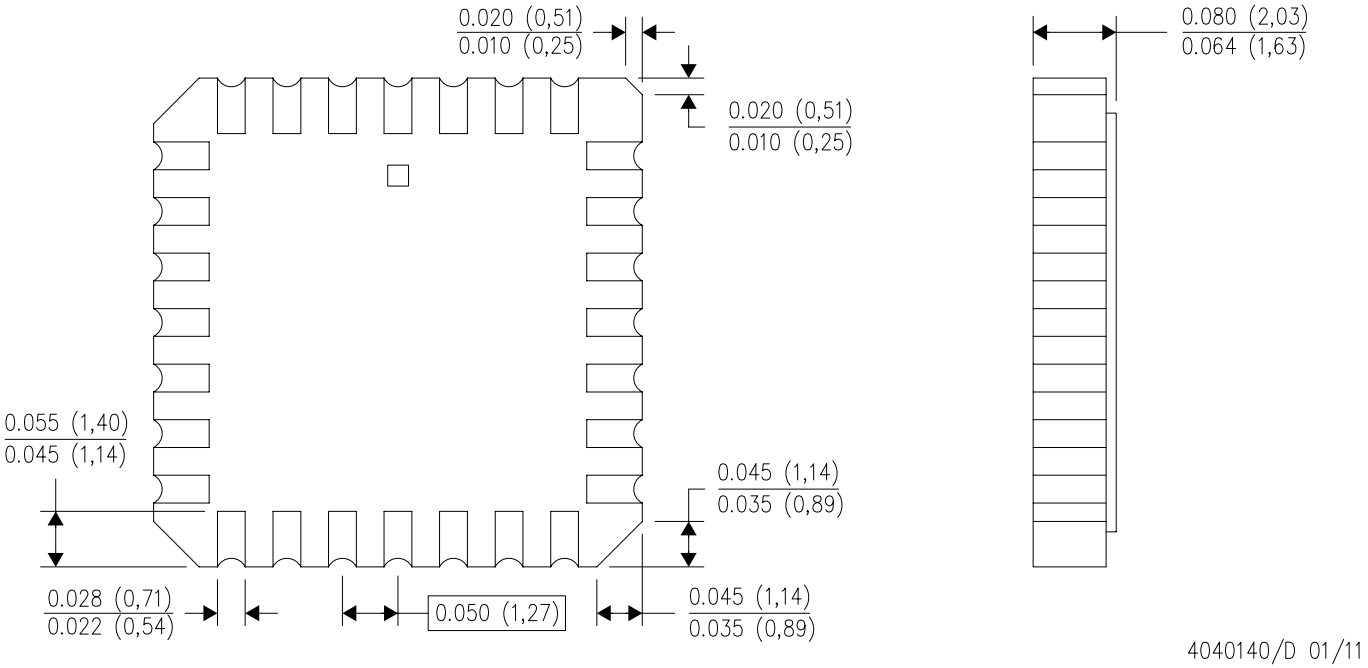
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only.
E. Falls within MIL STD 1835 GDFP1–F14

FK (S–CQCC–N**) LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



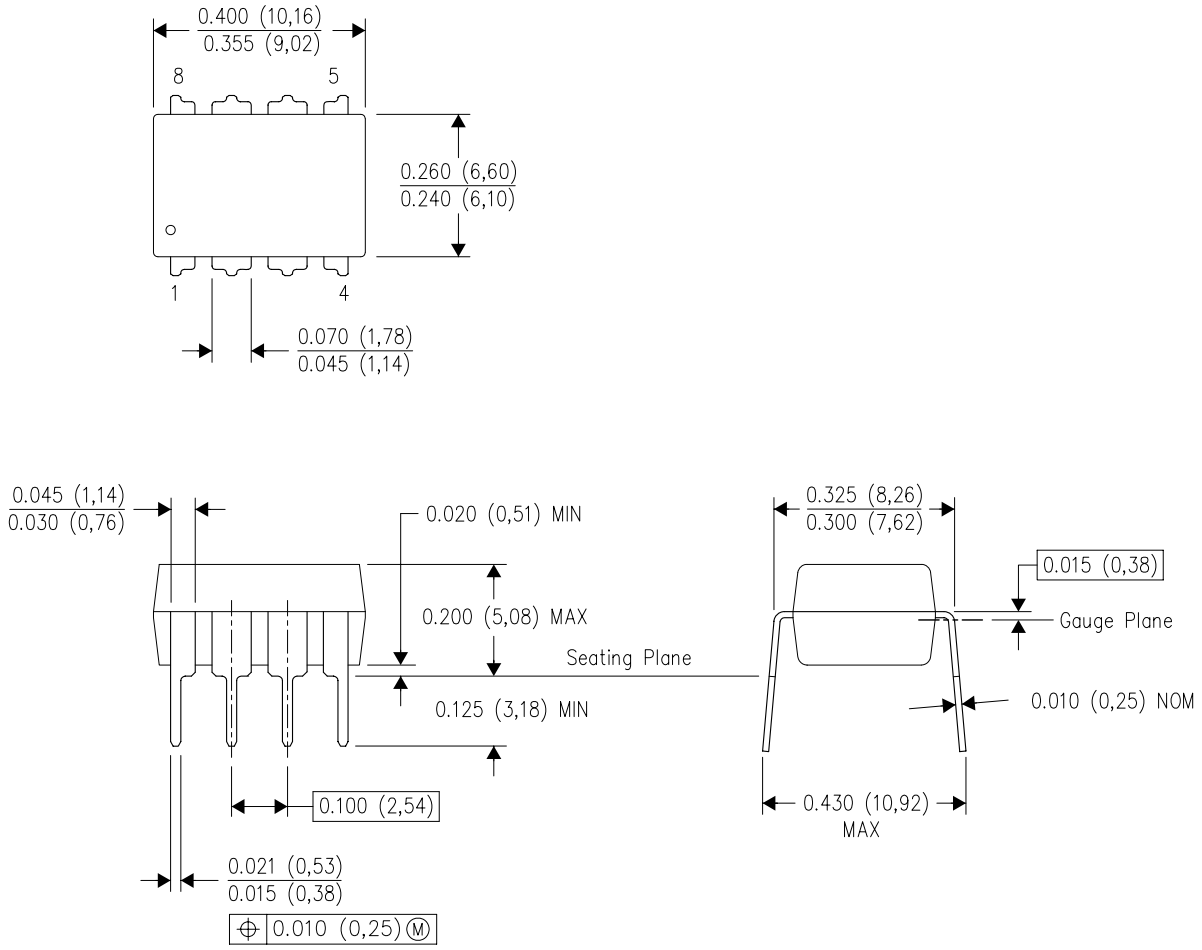
NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.740 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)



4040140/D 01/11

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a metal lid.
D. Falls within JEDEC MS–004

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE

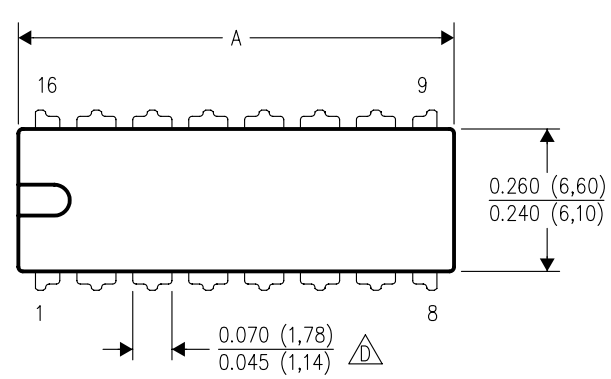


NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

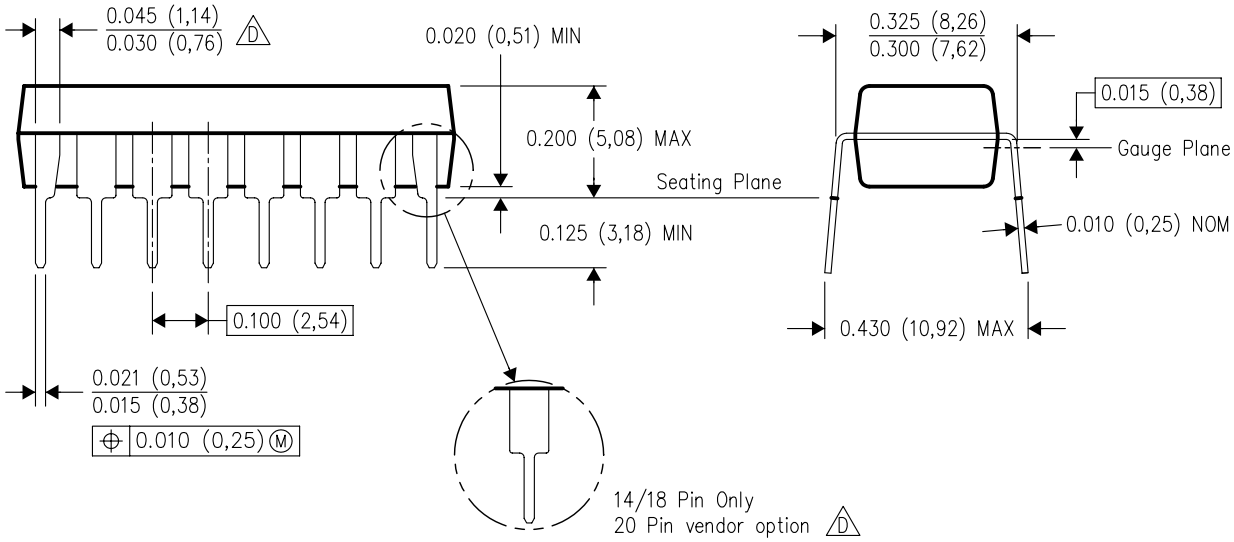
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



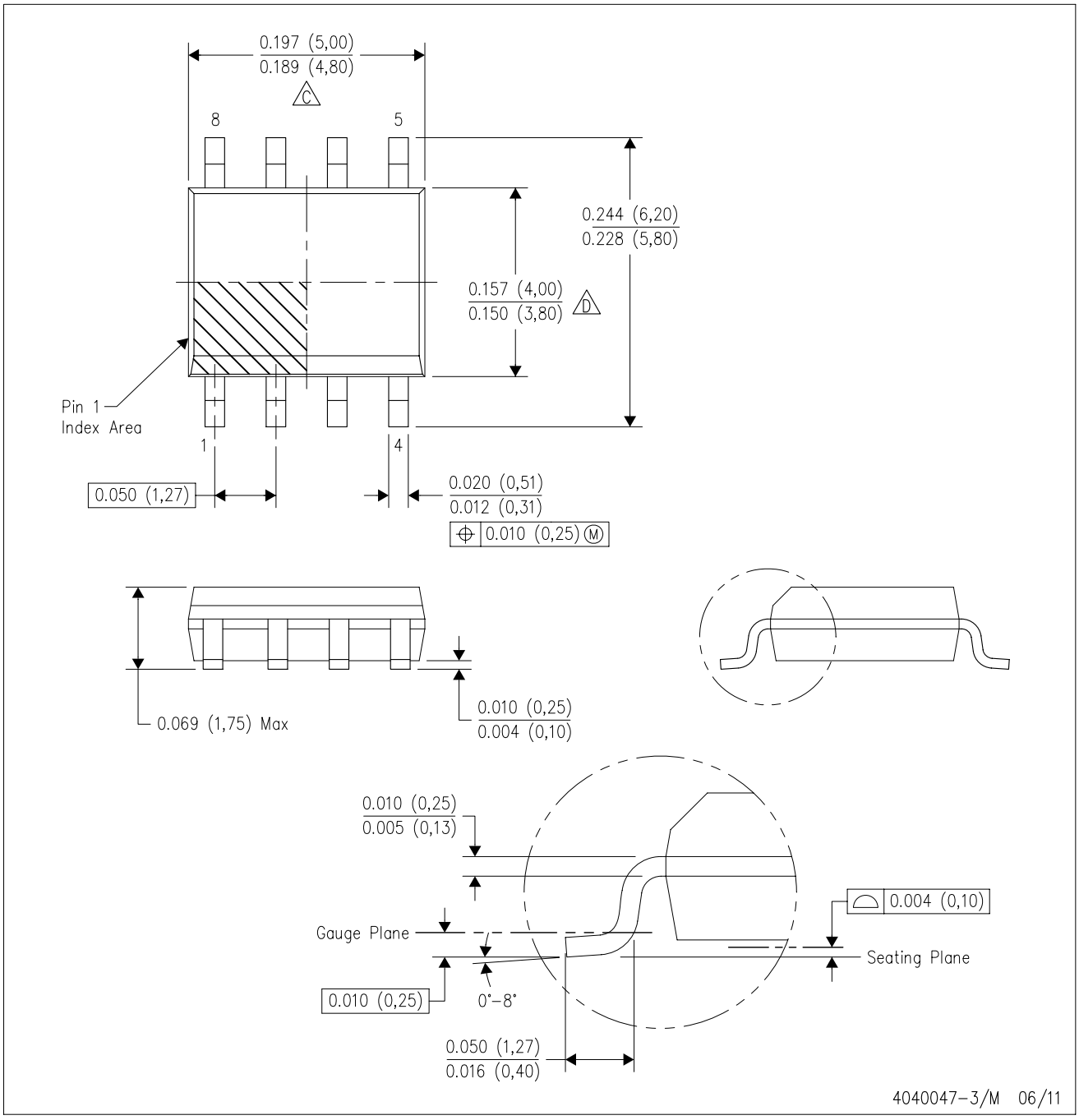
DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

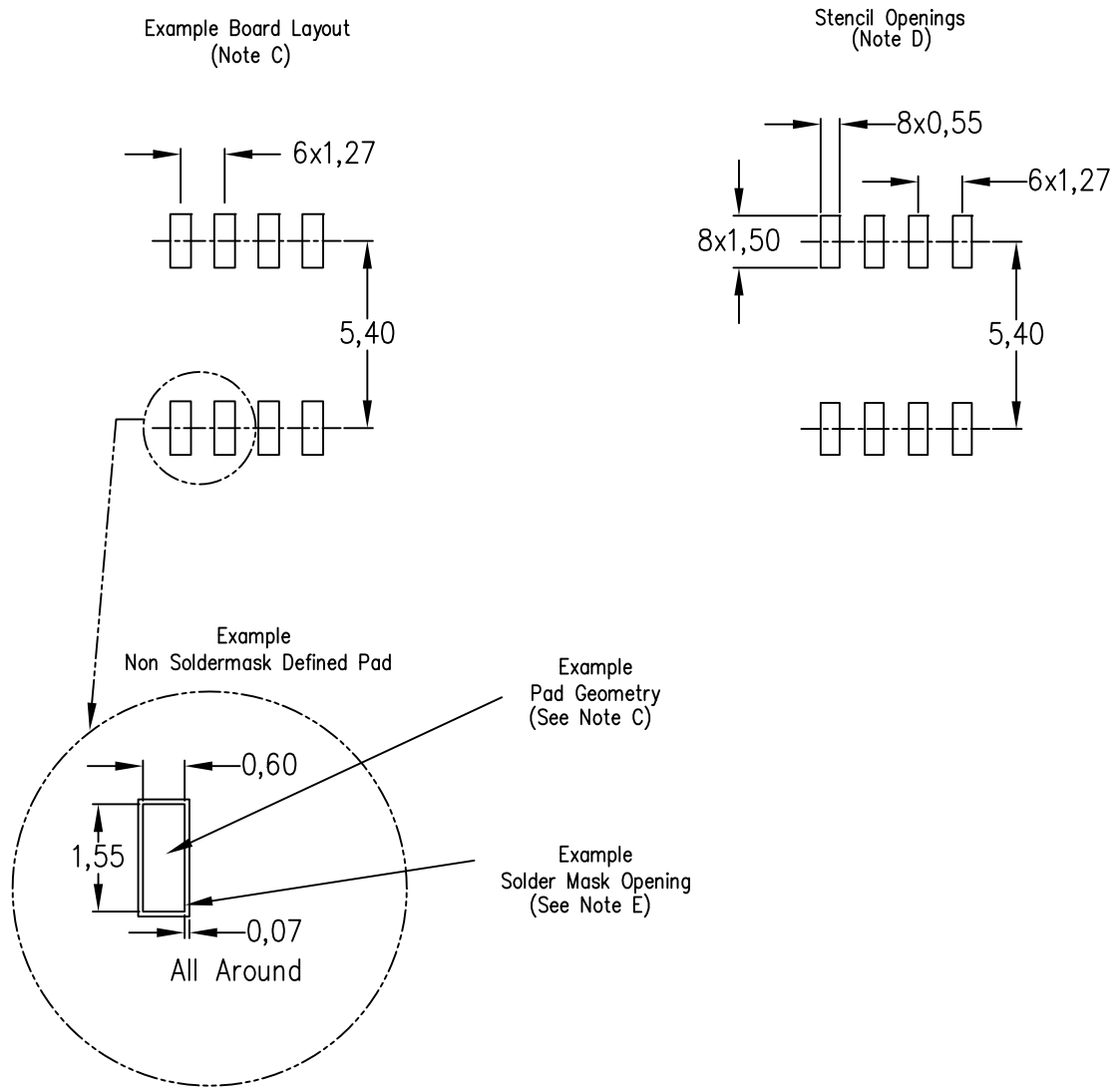
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



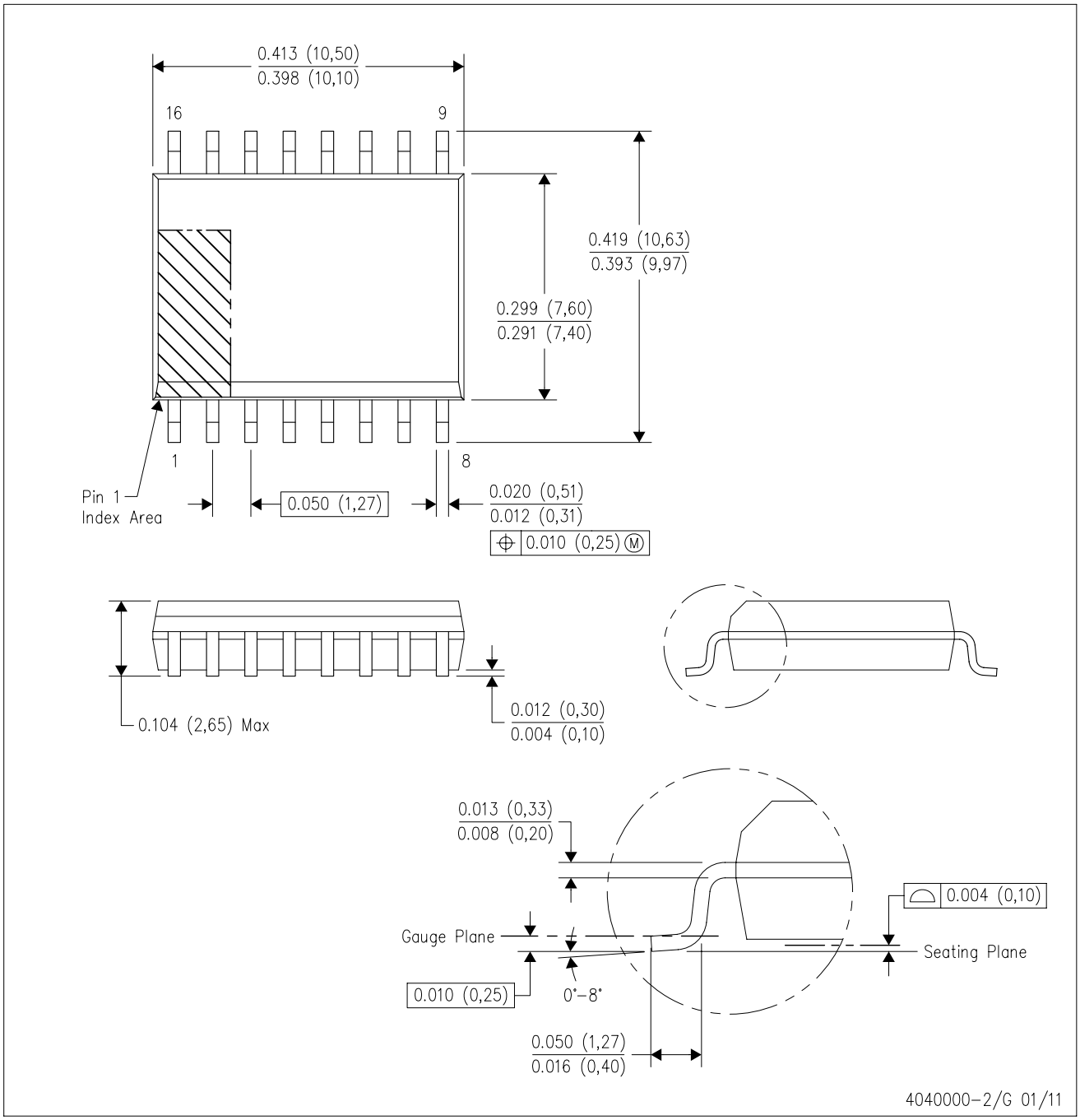
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DW (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS–013 variation AA.

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